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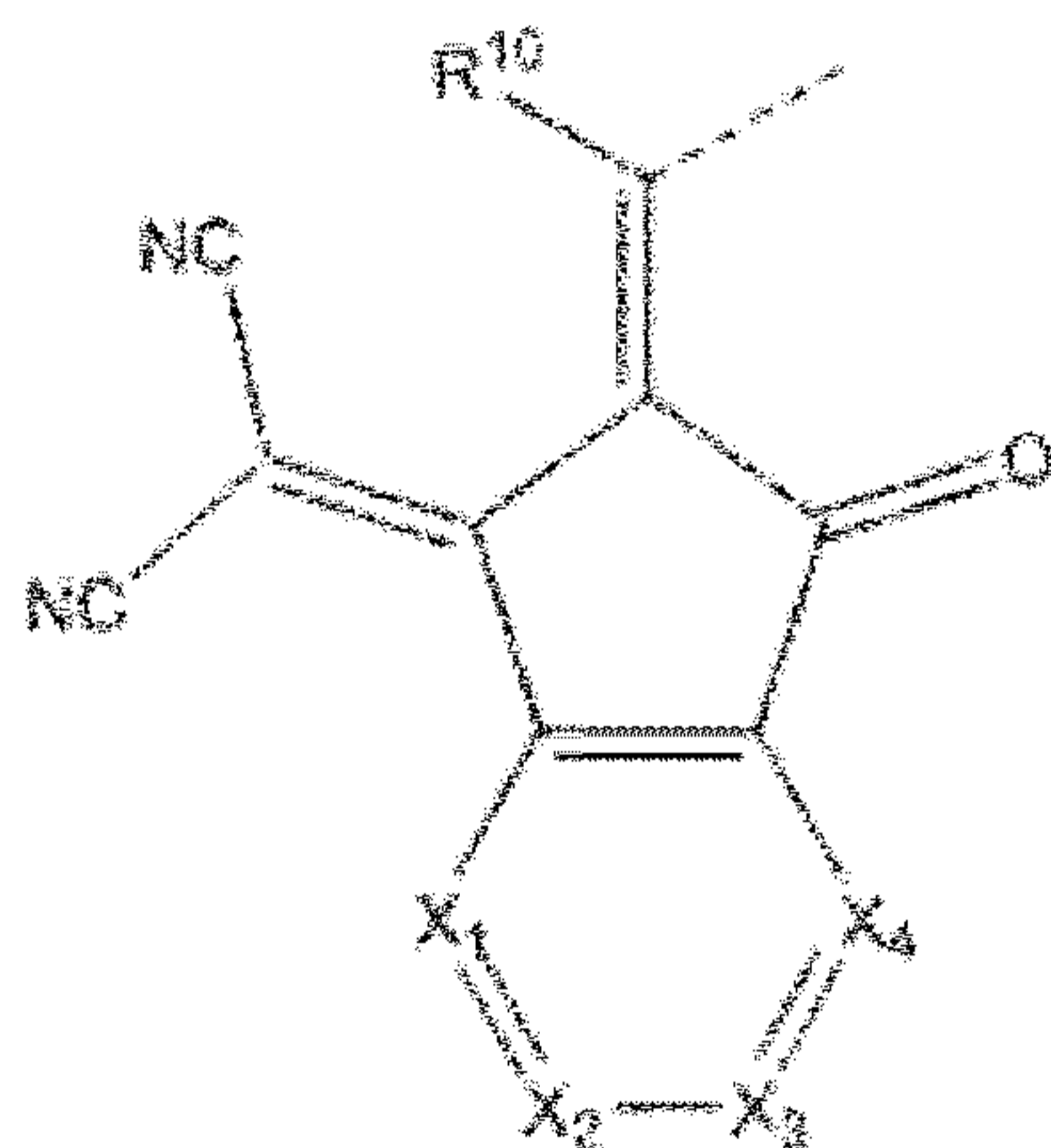
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(54) Title of the Invention: Photoactive compound
Abstract Title: Photoactive organic semiconductors comprising dicyanomethylene substituted pyridinyl electron accepting groups

(57) Photoactive organic semiconductors comprising dicyanomethylene substituted pyridinyl electron accepting groups



(II)

Compounds of the structure EAG-EDG-EAG, wherein EDG is an electron donating group comprising a polycyclic heteroaromatic group and each EAG is an electron accepting group of formula (II). The dashed bond of (II) is a bond to EDG. X¹-X⁴ are, independently, CR¹¹ or N wherein R¹¹ is H or a substituent. Most preferably, X³ is N and X¹, X² and X⁴ are CH (i.e. the hetero ring is a pyridine). Also disclosed are compounds (Ia) and (Ib) as described herein, which resemble IEICO-4F. Also disclosed is an organic photodetector comprising an anode, a cathode, and a photosensitive organic layer comprising EAG-EDG-EAG. EAG-EDG-EAG can absorb near-infra red light (>750 nanometres). Further disclosed is a photosensor comprising a light source and the organic photodetector mentioned herein. Disclosed is a method of using the said photodetector to determine the presence and/or concentration of a target material in a sample.

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FIGURE 1

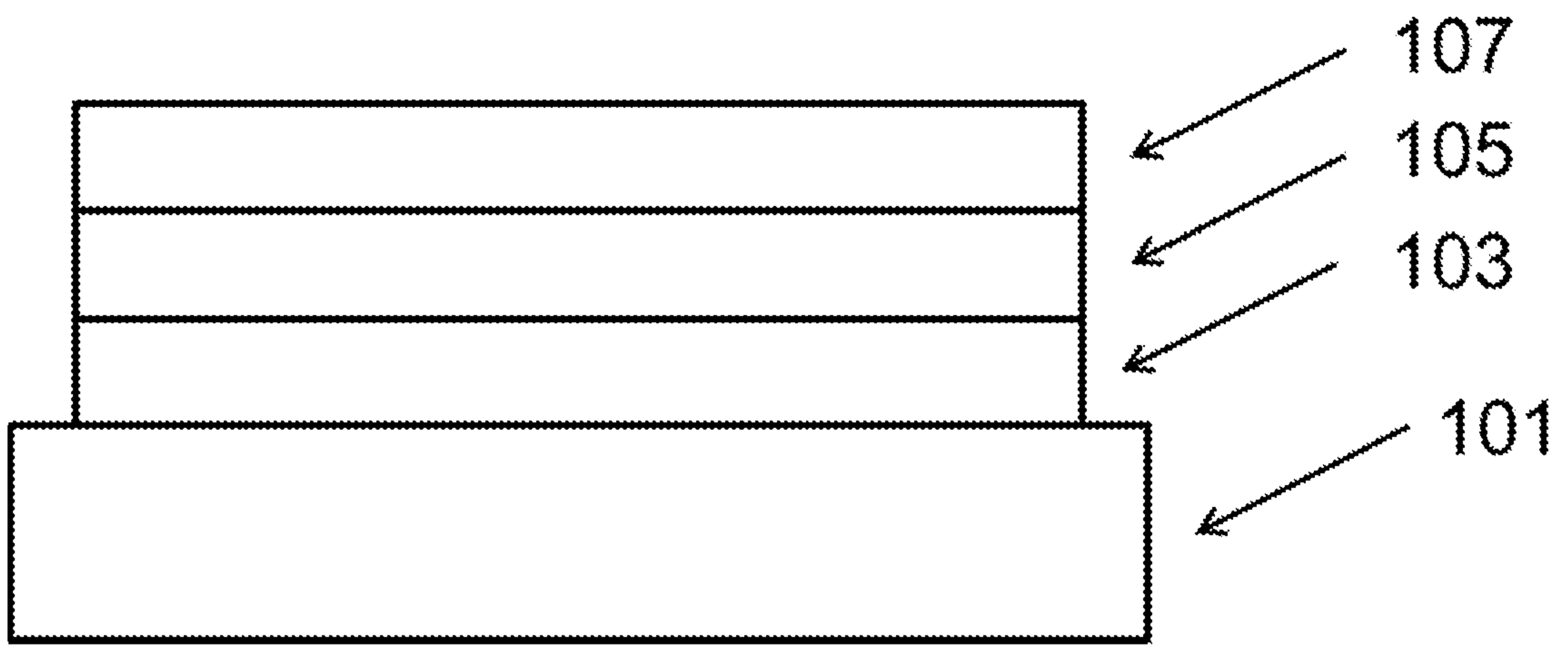
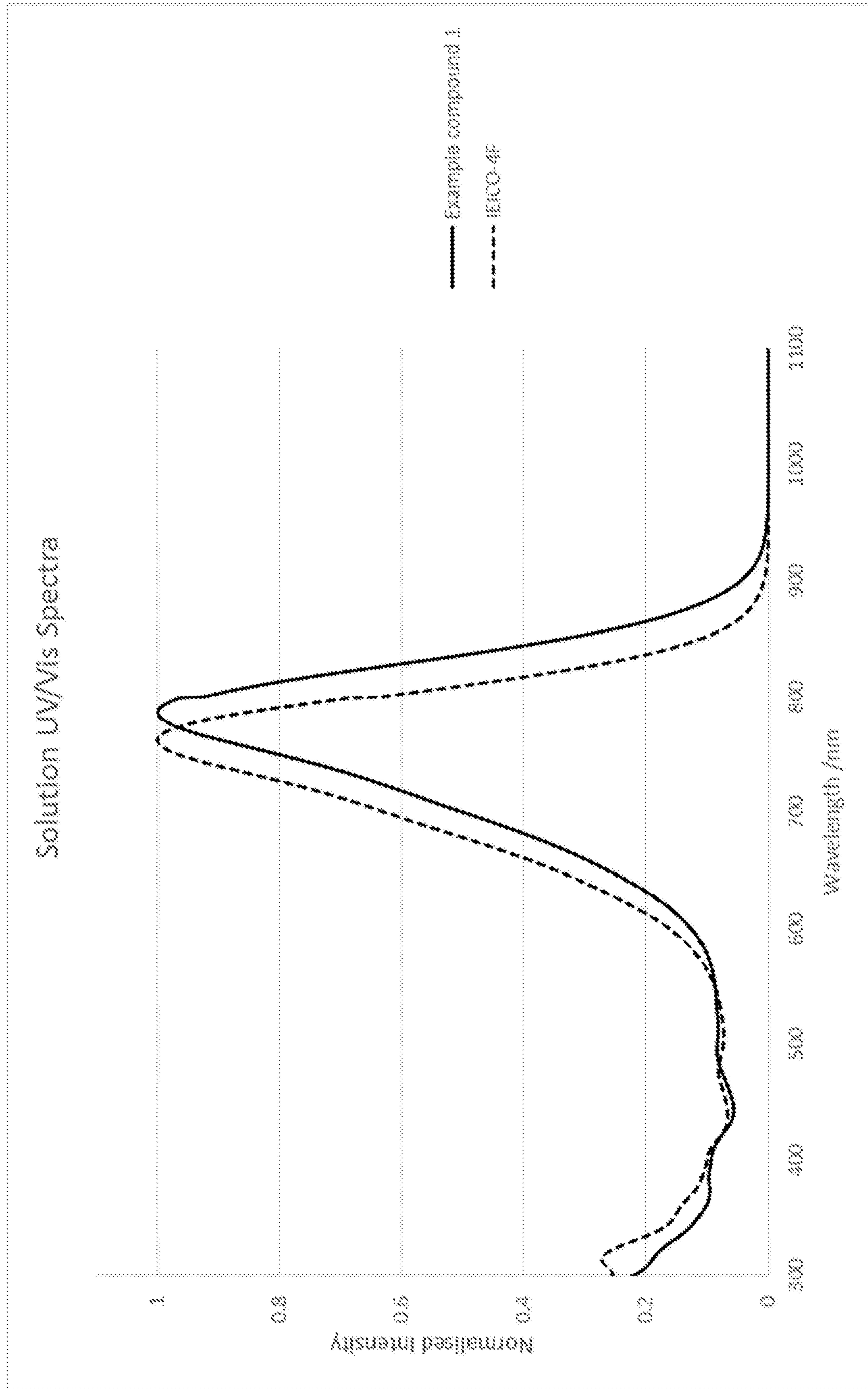


FIGURE 2





The following terms are registered trade marks and should be read as such wherever they occur in this document:

Gaussian09
Gaussian

PHOTOACTIVE COMPOUND

BACKGROUND

Embodiments of the present disclosure relate to photoactive compounds and their use in organic electronic devices, in particular organic photodetectors.

5 A range of organic electronic devices comprising organic semiconductor materials are known, including organic light-emitting devices, organic field effect transistors, organic photovoltaic devices and organic photodetectors (OPDs).

WO 2018/065352 discloses an OPD having a photoactive layer that contains a small molecule acceptor which does not contain a fullerene moiety and a conjugated
10 copolymer electron donor having donor and acceptor units.

WO 2018/065356 discloses an OPD having a photoactive layer that contains a small molecule acceptor which does not contain a fullerene moiety and a conjugated copolymer electron donor having randomly distributed donor and acceptor units.

Yao et al, "Design, Synthesis, and Photovoltaic Characterization of a Small Molecular
15 Acceptor with an Ultra-Narrow Band Gap", *Angew Chem Int Ed Engl.* 2017 Mar 6;56(11):3045-3049 discloses a non-fullerene acceptor with a band gap of 1.24 eV.

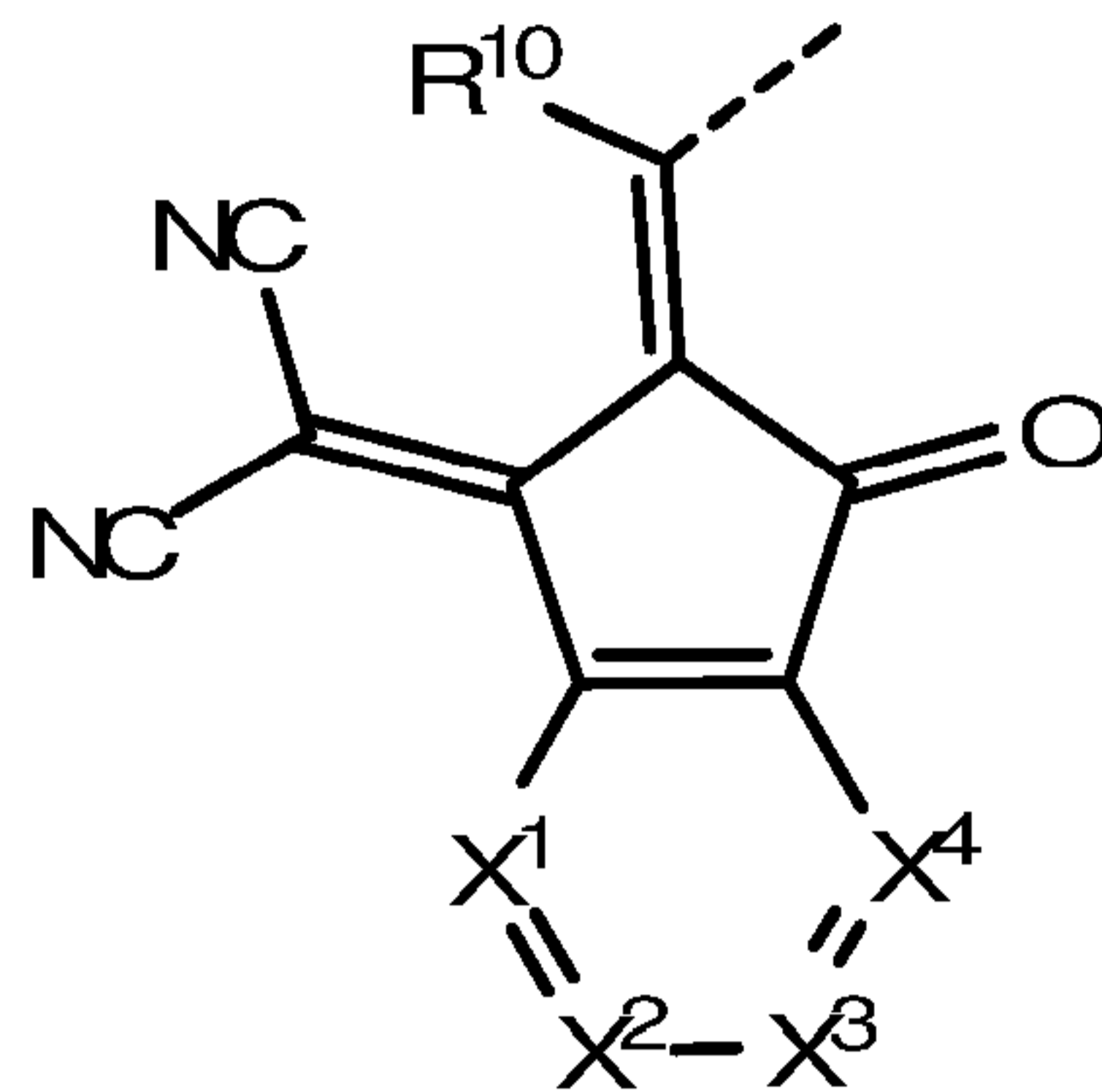
Summary

A summary of aspects of certain embodiments disclosed herein is set forth below. It should be understood that these aspects are presented merely to provide the reader with
20 a brief summary of these certain embodiments and that these aspects are not intended to limit the scope of this disclosure. Indeed, this disclosure may encompass a variety of aspects and/or a combination of aspects that may not be set forth.

Embodiments of the present disclosure provide a compound of formula (I):



wherein EDG is an electron-donating group comprising a polycyclic heteroaromatic group and each EAG is an electron-accepting group of formula (II):



(II)

5 wherein R¹⁰ in each occurrence is H or a substituent;

---- is a bond to EDG; and

each X¹-X⁴ is independently CR¹¹ or N wherein R¹¹ in each occurrence is H or a substituent, with the proviso that at least one occurrence of at least one of X¹-X⁴ is N.

The present inventors have found that compounds of formula (I) may be capable of
10 absorbing light at long wavelengths, e.g. greater than 750 nm, allowing for use of these compounds in organic photodetectors, particularly in a photosensor containing such an OPD and a near infra-red light source.

Accordingly, in some embodiments, there is provided a composition containing an
15 electron-accepting (n-type) compound as described herein and an electron donor (p-type) compound.

In some embodiments there formulation comprising a composition as described herein dissolved or dispersed in one or more solvents.

In some embodiments there is provided an organic photodetector having: an anode; a cathode; and a photosensitive organic layer disposed between the anode and cathode
20 wherein the photosensitive organic layer contains a donor compound and an acceptor compound of formula (I).

In some embodiments, there is provided a method of forming an organic photodetector as described herein comprising formation of the photosensitive organic layer over one of the anode and cathode and formation of the other of the anode and cathode over the photosensitive organic layer.

- 5 In some embodiments, there is provided a photosensor comprising a light source and an organic photodetector as described herein configured to detect light emitted from the light source.

In some embodiments, there is provided a method of determining the presence and / or concentration of a target material in a sample, the method comprising illuminating the
10 sample and measuring a response of an organic photodetector as described herein which is configured to receive light emitted from the sample upon illumination.

Description of Drawings

The disclosed technology and accompanying figures describe some implementations of the disclosed technology.

- 15 Figure 1 illustrates an organic photodetector according to some embodiments; and
Figure 2 illustrates absorption spectra for a compound according to some embodiments of the present disclosure and a comparative compound.

The drawings are not drawn to scale and have various viewpoints and perspectives. The drawings are some implementations and examples. Additionally, some components
20 and/or operations may be separated into different blocks or combined into a single block for the purposes of discussion of some of the embodiments of the disclosed technology. Moreover, while the technology is amenable to various modifications and alternative forms, specific embodiments have been shown by way of example in the drawings and are described in detail below. The intention, however, is not to limit the technology to
25 the particular implementations described. On the contrary, the technology is intended to cover all modifications, equivalents, and alternatives falling within the scope of the technology as defined by the appended claims.

Detailed Description

Unless the context clearly requires otherwise, throughout the description and the claims, the words "comprise," "comprising," and the like are to be construed in an inclusive sense, as opposed to an exclusive or exhaustive sense; that is to say, in the sense of "including, but not limited to." As used herein, the terms "connected," "coupled," or
5 any variant thereof means any connection or coupling, either direct or indirect, between two or more elements; the coupling or connection between the elements can be physical, logical, electromagnetic, or a combination thereof. Additionally, the words "herein," "above," "below," and words of similar import, when used in this application, refer to this application as a whole and not to any particular portions of this application. Where
10 the context permits, words in the Detailed Description using the singular or plural number may also include the plural or singular number respectively. The word "or," in reference to a list of two or more items, covers all of the following interpretations of the word: any of the items in the list, all of the items in the list, and any combination of the items in the list.

15 The teachings of the technology provided herein can be applied to other systems, not necessarily the system described below. The elements and acts of the various examples described below can be combined to provide further implementations of the technology. Some alternative implementations of the technology may include not only additional elements to those implementations noted below, but also may include fewer elements.

20 These and other changes can be made to the technology in light of the following detailed description. While the description describes certain examples of the technology, and describes the best mode contemplated, no matter how detailed the description appears, the technology can be practiced in many ways. Details of the system may vary considerably in its specific implementation, while still being
25 encompassed by the technology disclosed herein. As noted above, particular terminology used when describing certain features or aspects of the technology should not be taken to imply that the terminology is being redefined herein to be restricted to any specific characteristics, features, or aspects of the technology with which that terminology is associated. In general, the terms used in the following claims should not
30 be construed to limit the technology to the specific examples disclosed in the specification, unless the Detailed Description section explicitly defines such terms.

Accordingly, the actual scope of the technology encompasses not only the disclosed examples, but also all equivalent ways of practicing or implementing the technology under the claims.

To reduce the number of claims, certain aspects of the technology are presented below
5 in certain claim forms, but the applicant contemplates the various aspects of the technology in any number of claim forms. For example, while some aspect of the technology may be recited as a computer-readable medium claim, other aspects may likewise be embodied as a computer-readable medium claim, or in other forms, such as being embodied in a means-plus-function claim.

10 In the following description, for the purposes of explanation, numerous specific details are set forth in order to provide a thorough understanding of implementations of the disclosed technology. It will be apparent, however, to one skilled in the art that embodiments of the disclosed technology may be practiced without some of these specific details.

15 Figure 1 illustrates an OPD according to some embodiments of the present disclosure. The OPD comprises a cathode 103, an anode 107 and a bulk heterojunction layer 105 disposed between the anode and the cathode. The OPD may be supported on a substrate 101, optionally a glass or plastic substrate.

Figure 1 illustrates an arrangement in which the cathode is disposed between the
20 substrate and the anode. In other embodiments, the anode may be disposed between the cathode and the substrate.

The bulk heterojunction layer comprises a mixture of an electron acceptor and an electron donor. Optionally, the bulk heterojunction layer consists of the electron acceptor and the electron donor.

25 Each of the anode and cathode may independently be a single conductive layer or may comprise a plurality of layers.

The OPD may comprise layers other than the anode, cathode and bulk shown in Figure 1. In some embodiments, a hole-transporting layer is disposed between the anode and

the bulk heterojunction layer. In some embodiments, an electron-transporting layer is disposed between the cathode and the bulk heterojunction layer. In some embodiments, a work function modification layer is disposed between the bulk heterojunction layer and the anode, and / or between the bulk heterojunction layer and the cathode.

5 In use, the photodetectors as described in this disclosure may be connected to a voltage source for applying a reverse bias to the device and / or a device configured to measure photocurrent. The voltage applied to the photodetectors may be variable. In some
10 embodiments, the photodetector may be continuously biased when in use.

In some embodiments, a photodetector system comprises a plurality of photodetectors
10 as described herein, such as an image sensor of a camera.

In some embodiments, a sensor may comprise an OPD as described herein and a light source wherein the OPD is configured to receive light emitted from the light source.

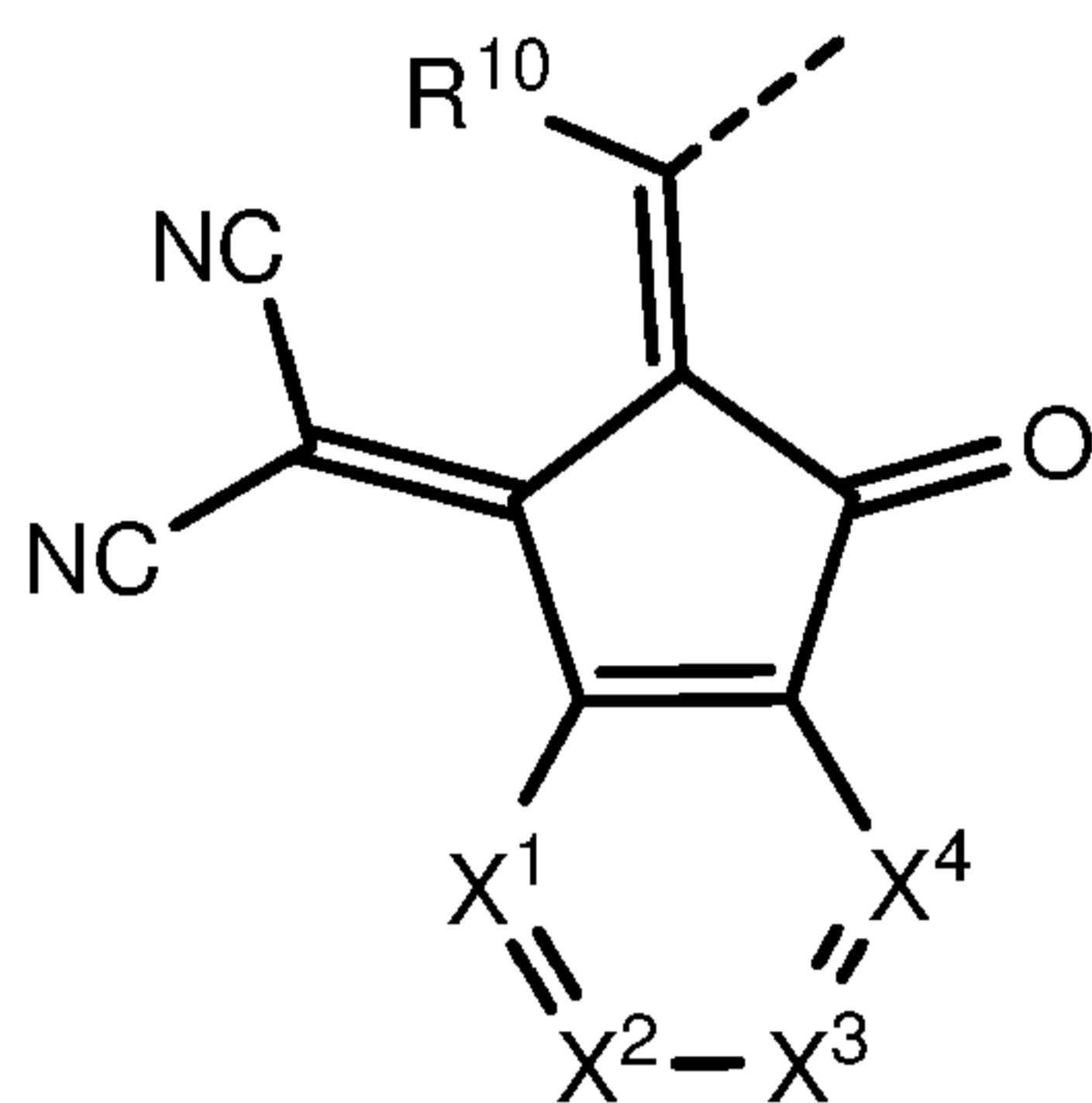
In some embodiments, the light from the light source may or may not be changed before
15 reaching the OPD. For example, the light may be filtered, down-converted or up-converted before it reaches the OPD.

The bulk heterojunction layer may contain an electron acceptor (n-type) compound of formula (I):



(I)

20 wherein EDG is an electron-donating group comprising a polycyclic heteroaromatic group and each EAG is an electron-accepting group of formula (II):



(II)

wherein R¹⁰ in each occurrence is H or a substituent;

---- is a bond to EDG; and

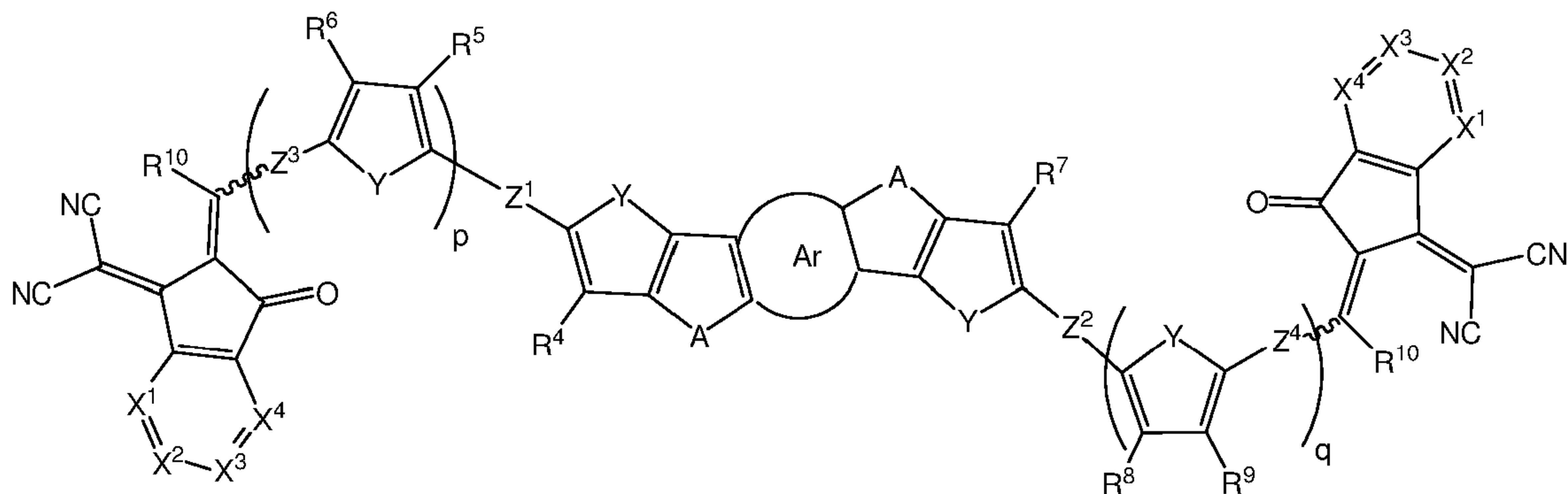
5 each X¹-X⁴ is independently CR¹¹ or N wherein R¹¹ in each occurrence is H or a substituent, with the proviso that at least one occurrence of at least one of X¹-X⁴ is N.

Optionally, each X³ is N.

Optionally, each X¹, X² and X⁴ is CR¹¹.

10 Optionally, each R¹¹ is independently selected from H and C₁₋₁₂ alkyl.

Optionally, the compound of formula (I) has formula (Ia):



(Ia)

15 wherein:

Ar is furan, thiophene or benzene which is unsubstituted or substituted with one or more substituents;

each Y is independently O or S;

5 each A is independently O, S or CR¹R² wherein R¹ and R² independently in each occurrence is a substituent;

each R⁴-R⁹ is independently H or a substituent;

p is 0, 1, 2 or 3;

q is 0, 1, 2 or 3;

10 Z¹ is a direct bond or, together with R⁴ or R⁵, forms an aromatic or heteroaromatic group Ar¹;

Z² is a direct bond or, together with R⁷ or R⁸, forms an aromatic or heteroaromatic group Ar²;

Z³ is a direct bond or, together with R⁶, forms an aromatic or heteroaromatic group Ar³;
and

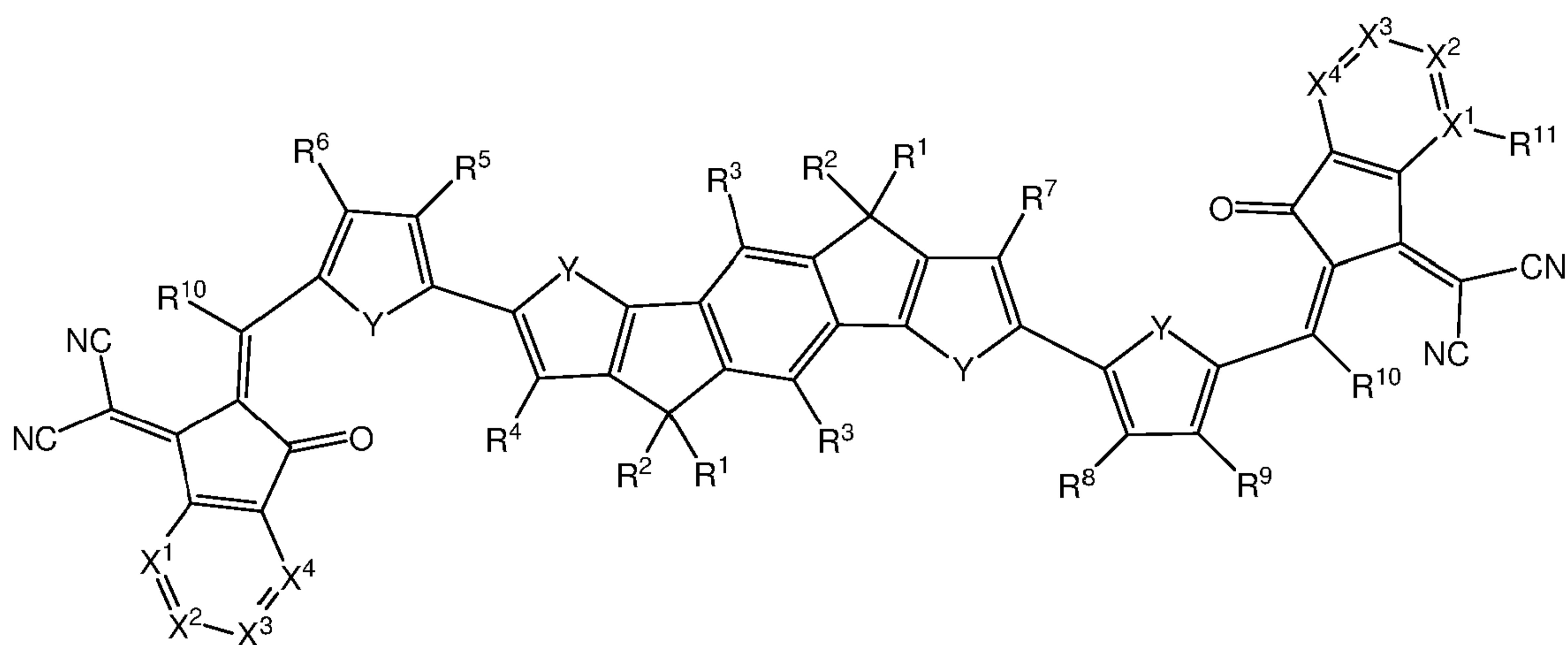
15 Z⁴ is a direct bond or, together with R⁹, forms an aromatic or heteroaromatic group Ar⁴.

In some embodiments, each Z¹ – Z⁴ is a direct bond.

In embodiments where one or more of Z¹ – Z⁴ forms part of an aromatic or heteroaromatic group Ar¹-Ar⁴, respectively, each Ar¹-Ar⁴ (where present) is preferably a thiophene.

20 Ar¹-Ar⁴ are each independently unsubstituted or substituted with one or more substituents. Optionally, substituents of Ar¹-Ar⁴ are selected from C₁₋₁₂ alkyl wherein one or more non-adjacent, non-terminal C atoms may be replaced with O, S, COO or CO.

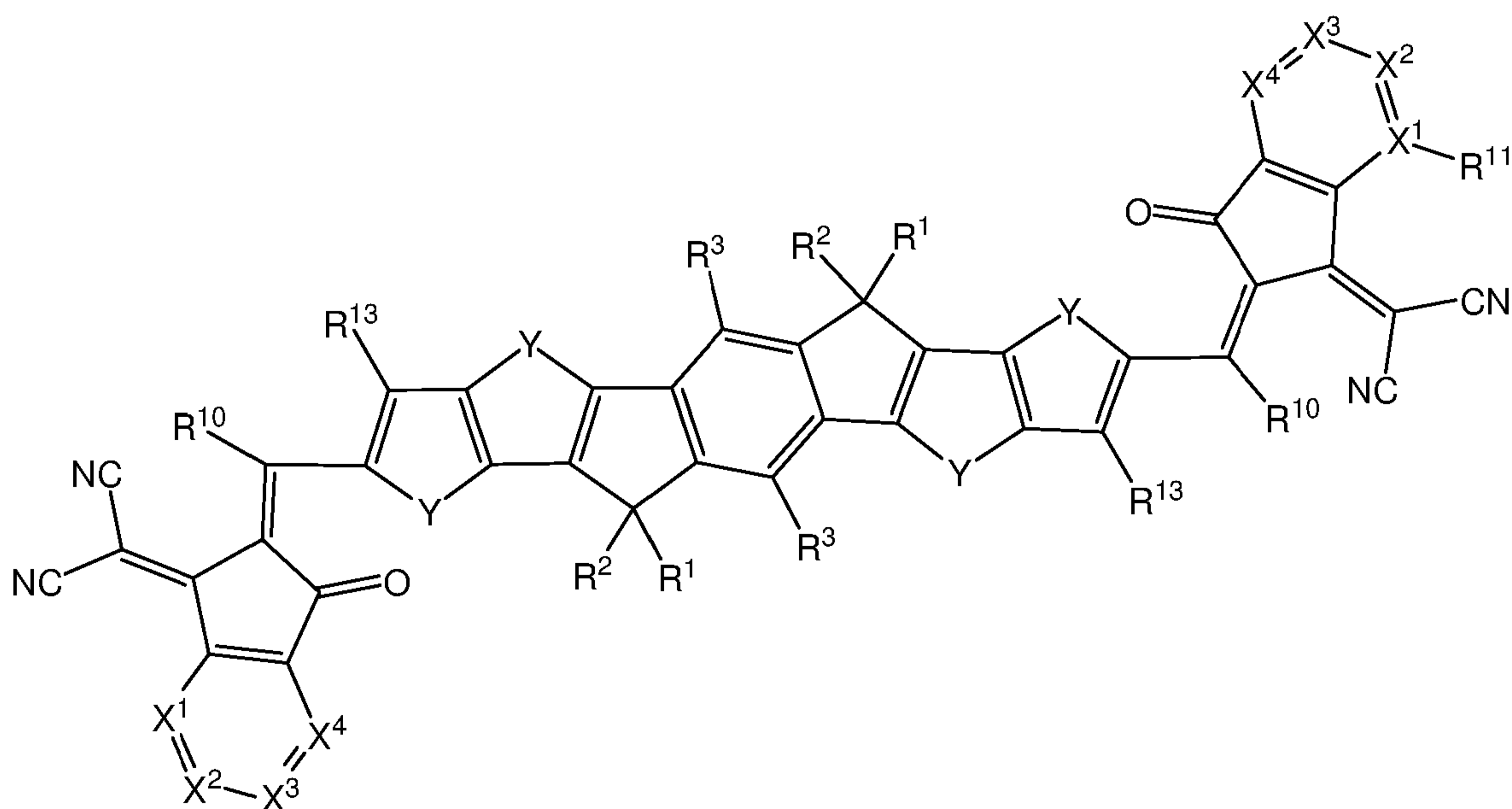
Optionally, the compound of formula (I) has formula (Ib):



(Ib)

wherein each R^3 is, independently in each occurrence, H or a substituent.

Optionally, the compound of formula (I) has formula (Ic):



5

(Ic)

wherein R^{13} in each occurrence is independently H or a substituent, optionally H or C_{1-12} alkyl wherein one or more non-adjacent, non-terminal C atoms may be replaced with O, S, COO or CO.

Optionally, R^1 and R^2 of formula (Ia), (Ib) or (Ic) independently in each occurrence are selected from the group consisting of:

5 linear, branched or cyclic C_{1-20} alkyl wherein one or more non-adjacent, non-terminal C atoms may be replaced by O, S, NR^{12} , CO or COO wherein R^{12} is a C_{1-12} hydrocarbyl and one or more H atoms of the C_{1-20} alkyl may be replaced with F; and

a group of formula $(Ak)_u-(Ar^6)_v$ wherein Ak is a C_{1-12} alkylene chain in which one or more C atoms may be replaced with O, S, CO or COO; u is 0 or 1; Ar^6 in each occurrence is independently an aromatic or heteroaromatic group which is unsubstituted or substituted with one or more substituents; and v is at least 1, optionally 1, 2 or 3.

10 Ar^6 is preferably phenyl.

Where present, substituents of Ar^6 may be a substituent R^{14} wherein R^{14} in each occurrence is independently selected from C_{1-20} alkyl wherein one or more non-adjacent, non-terminal C atoms may be replaced by O, S, NR^{12} , CO or COO and one or more H atoms of the C_{1-20} alkyl may be replaced with F.

15 A hydrocarbyl group as described herein is optionally selected from C_{1-20} alkyl; unsubstituted phenyl; and phenyl substituted with one or more C_{1-12} alkyl groups.

If p is 3 or more then $-(Ar^6)_v$ may be a linear or branched chain of Ar^6 groups. A linear chain of Ar^6 groups as described herein has only one monovalent terminal Ar^6 group whereas a branched chain of Ar^6 groups has at least two monovalent terminal Ar^6 groups.

Optionally, at least one of R^1 and R^2 in each occurrence, optionally each R^1 and R^2 , is phenyl which is unsubstituted or substituted with one or more substituents selected from R^{14} as described above.

Optionally, each R^4 - R^9 of formula (Ia) or (Ib) is independently selected from:

25 H;

C_{1-12} alkyl wherein one or more non-adjacent, non-terminal C atoms may be replaced with O, S, COO or CO; and

an aromatic or heteroaromatic group Ar^5 which is unsubstituted or substituted with one or more substituents.

Optionally, each R^3 of formula (Ib) independently in each occurrence is selected from:

H;

5 C_{1-12} alkyl wherein one or more non-adjacent, non-terminal C atoms may be replaced with O, S, COO or CO; and

an aromatic or heteroaromatic group Ar^5 which is unsubstituted or substituted with one or more substituents.

Ar^5 is preferably an aromatic group, more preferably phenyl.

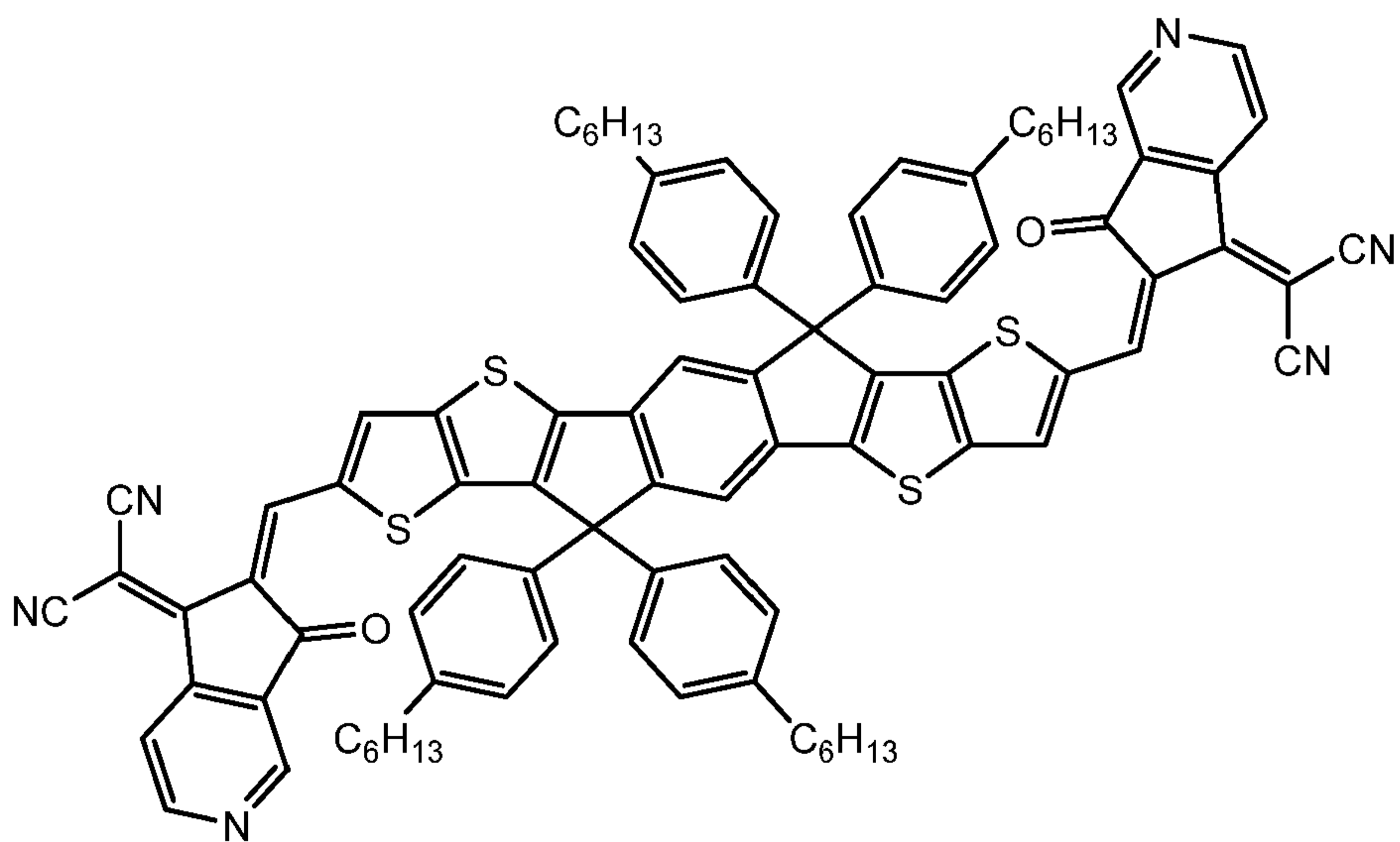
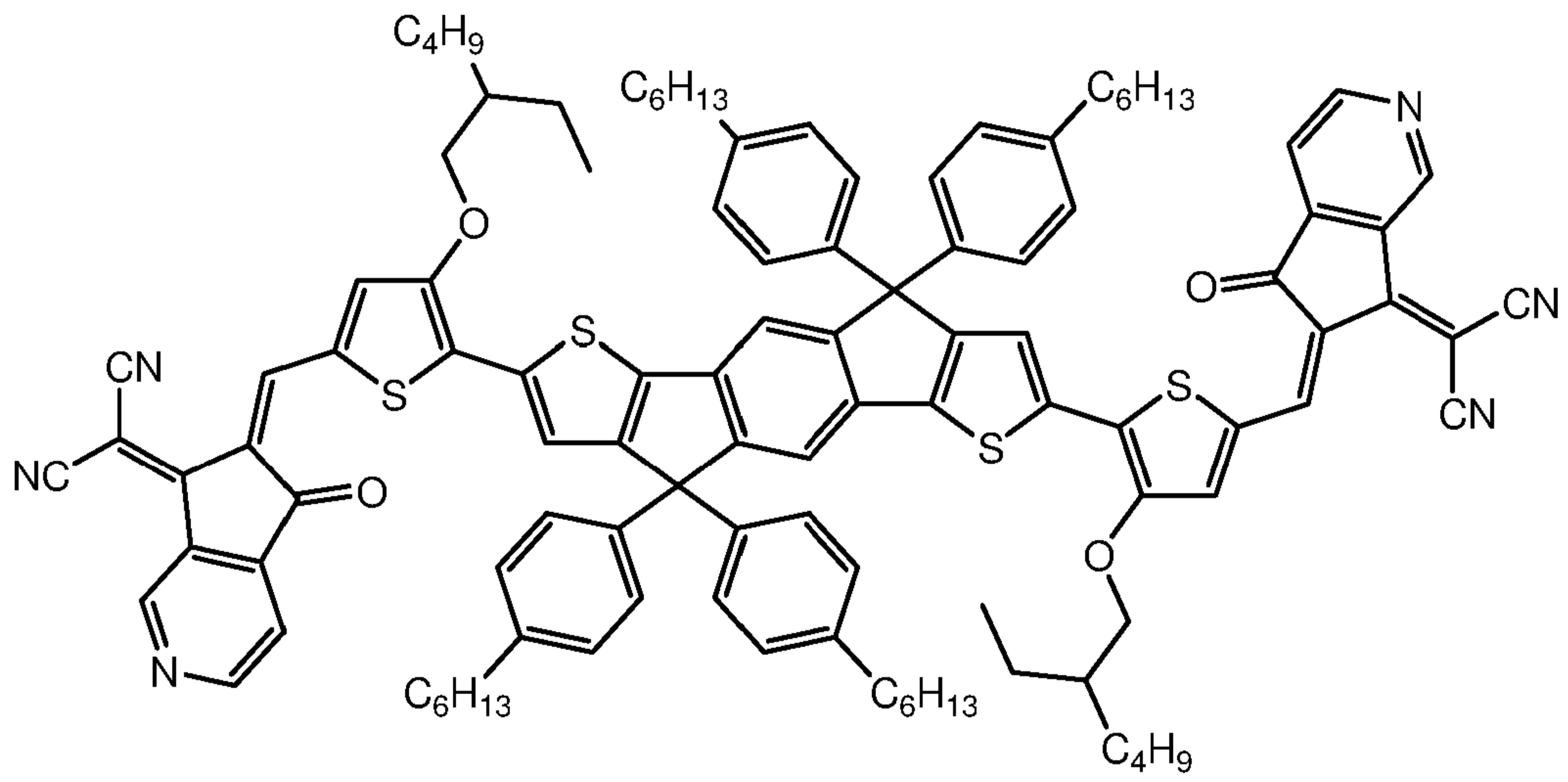
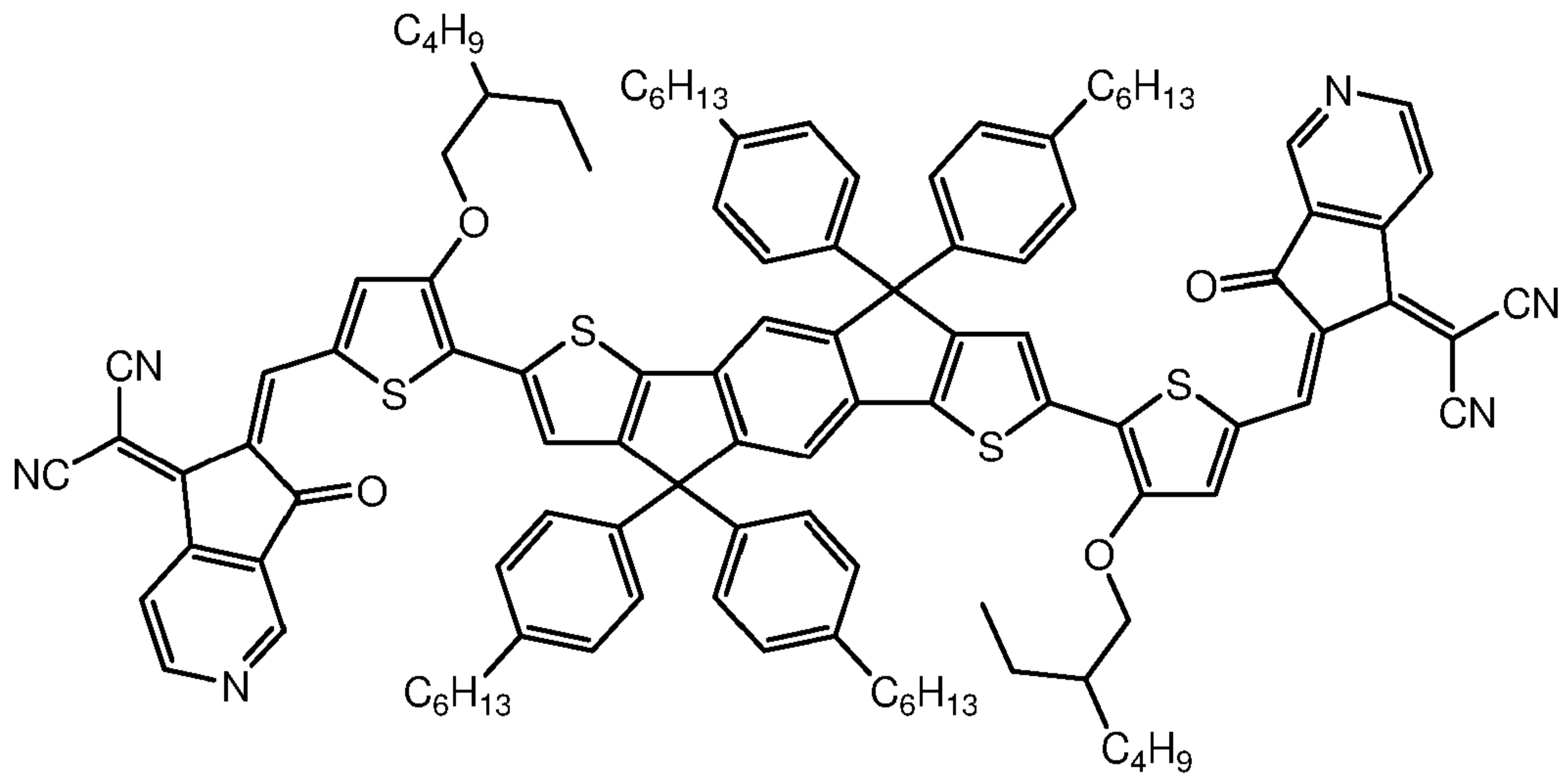
10 The one or more substituents of Ar^5 , if present, may be selected from C_{1-12} alkyl wherein one or more non-adjacent, non-terminal C atoms may be replaced with O, S, COO or CO.

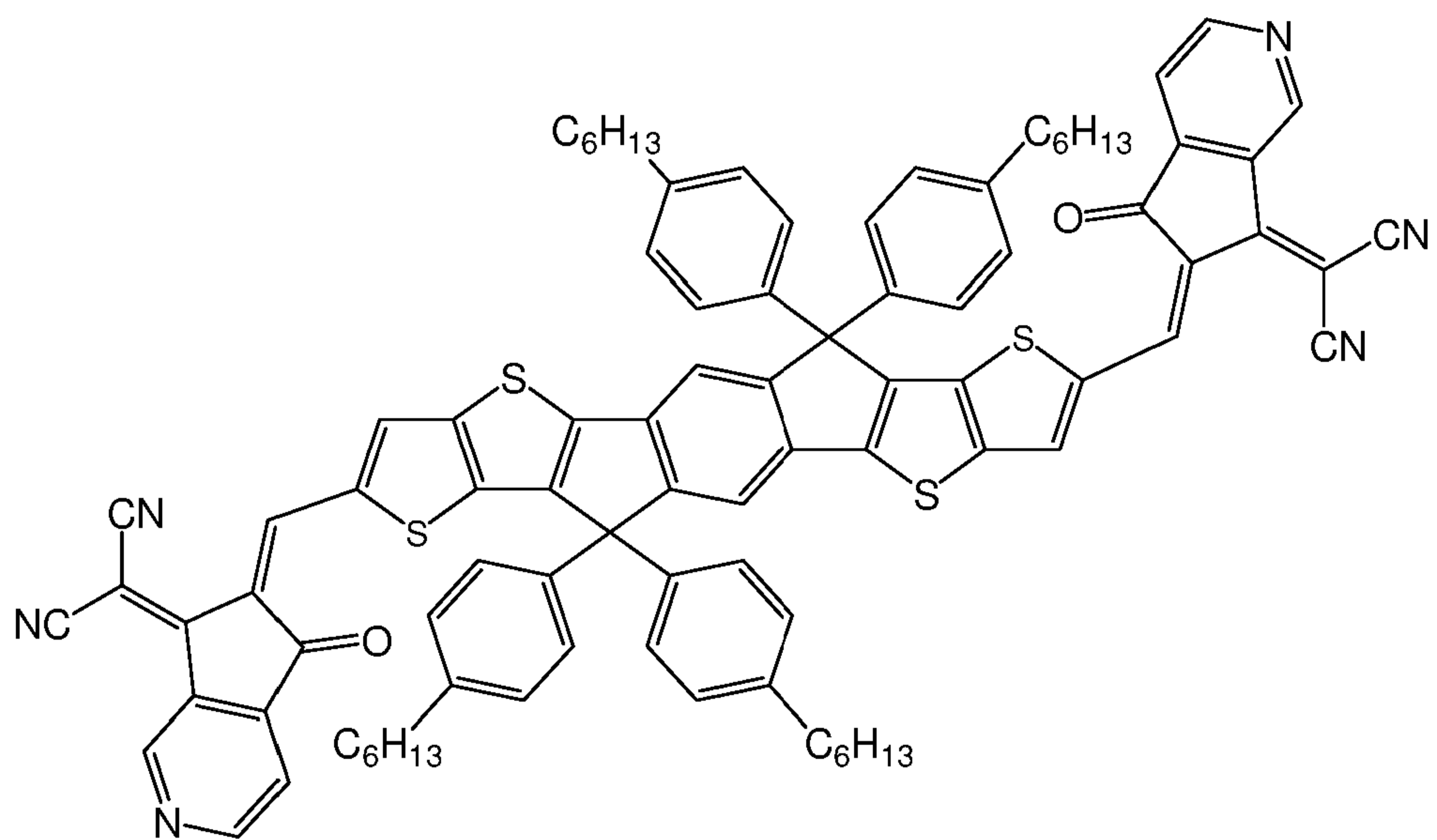
In some embodiments, each R^3 - R^{10} is H; C_{1-20} alkyl; or C_{1-20} alkoxy.

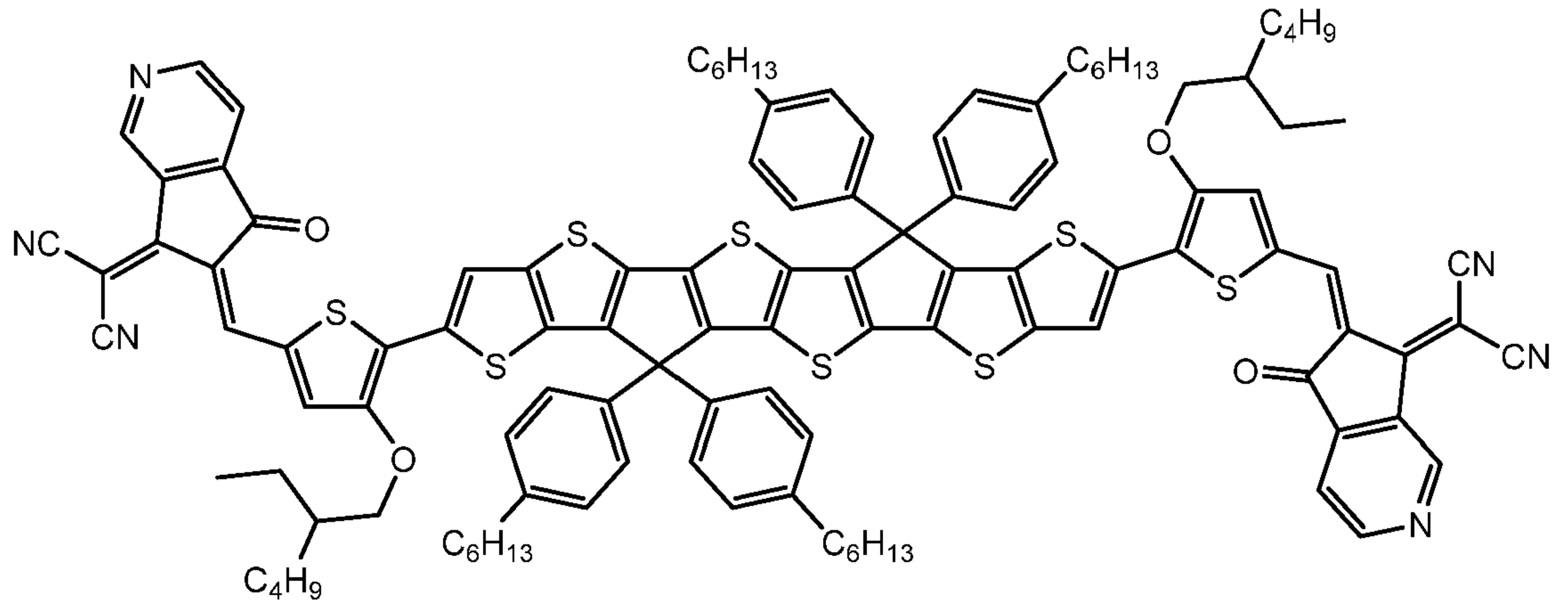
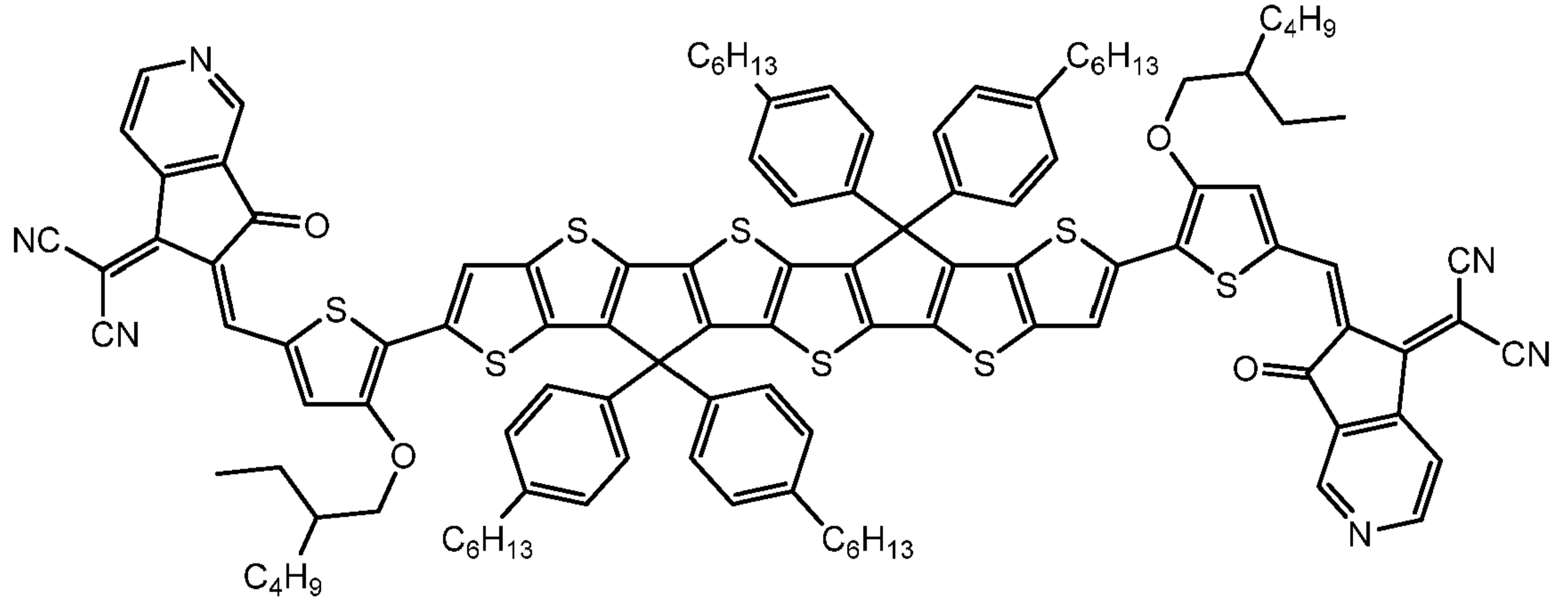
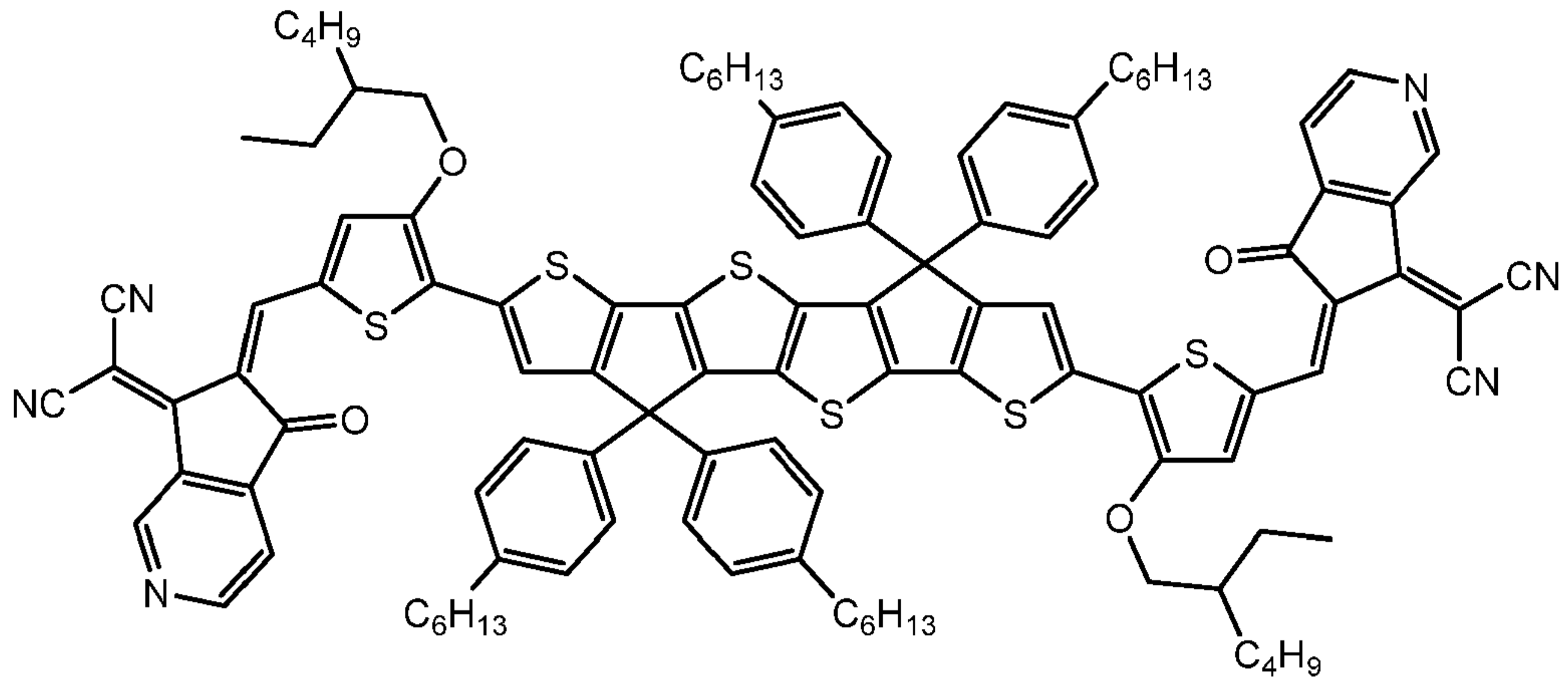
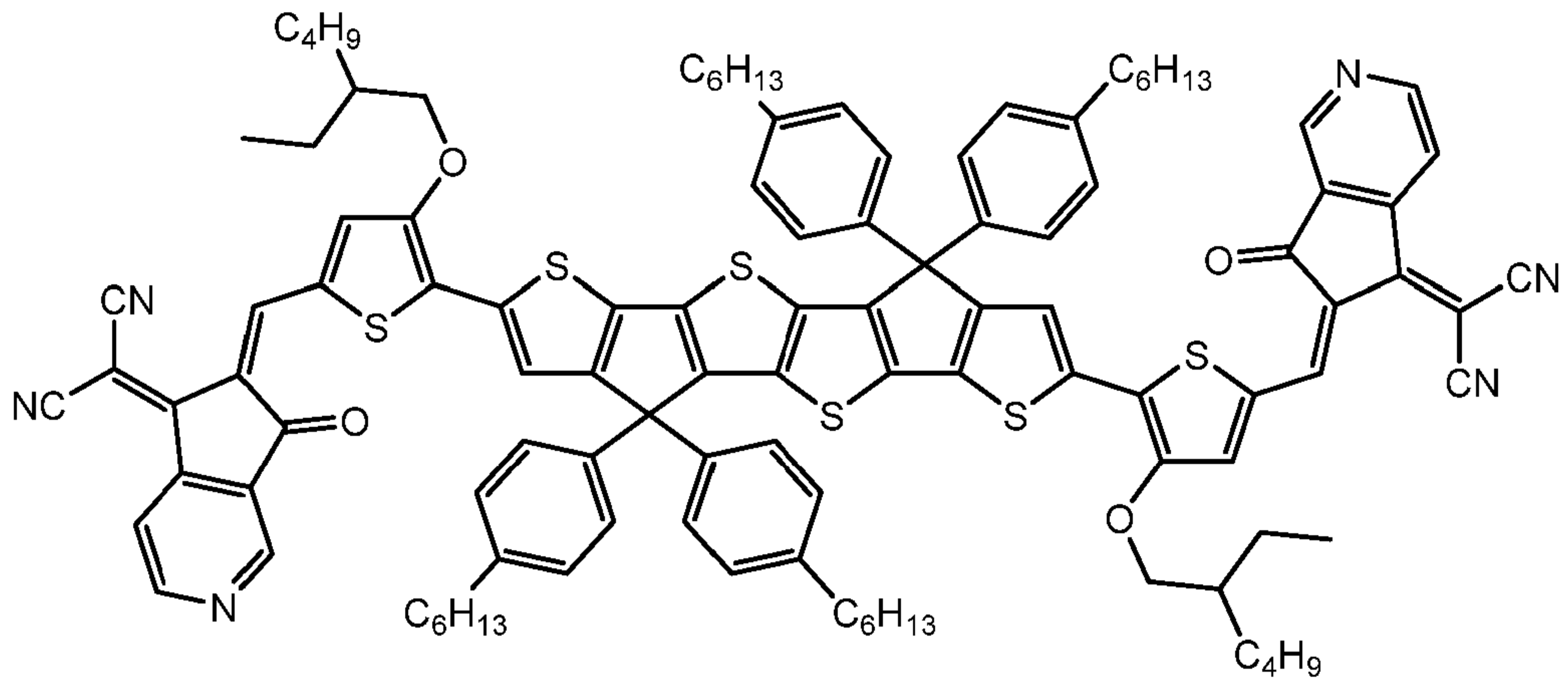
15 In some embodiments at least one of, optionally both of, R^5 and R^8 is not H, and each R^3 , R^4 and R^6 - R^{10} is H.

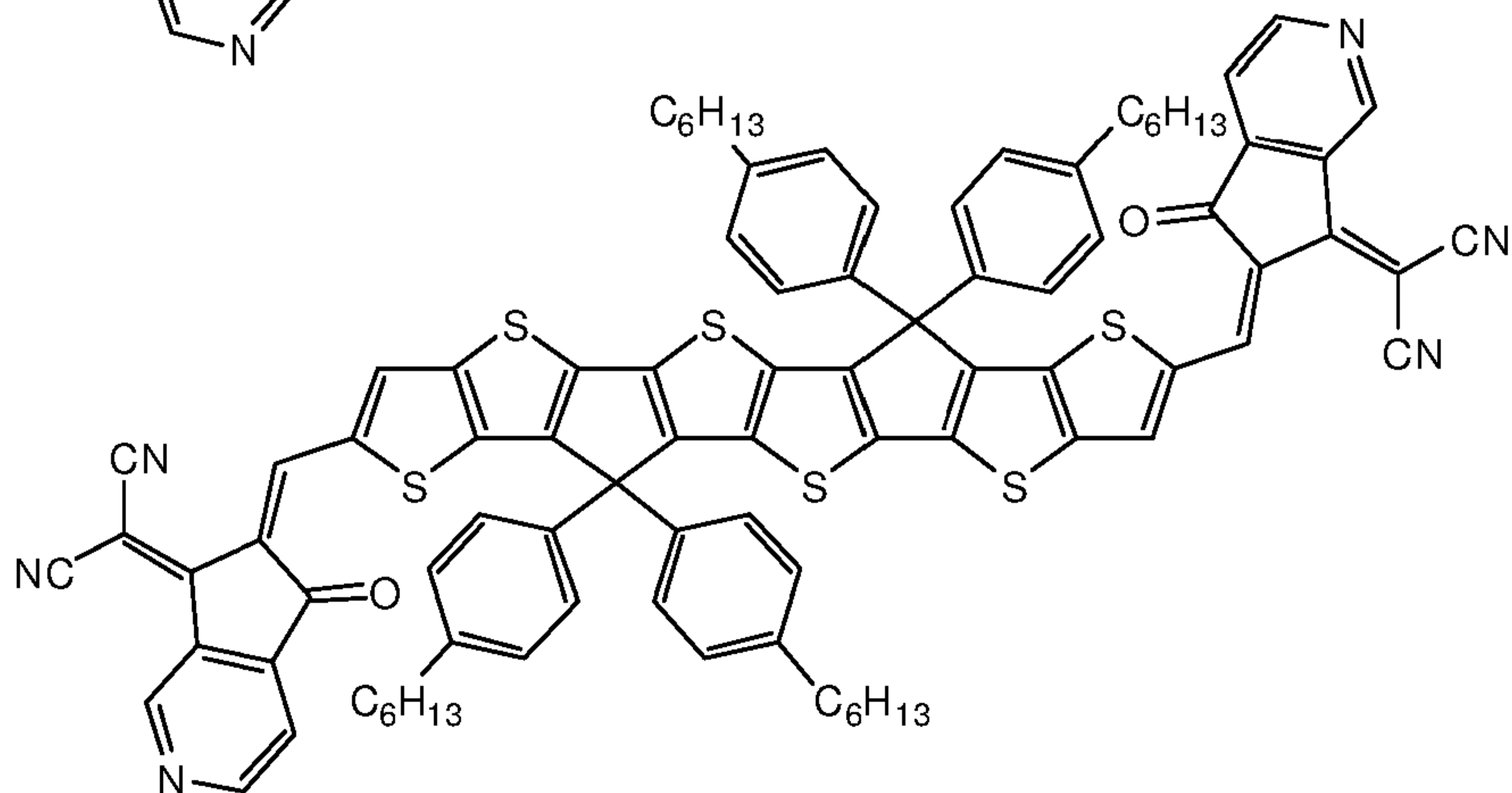
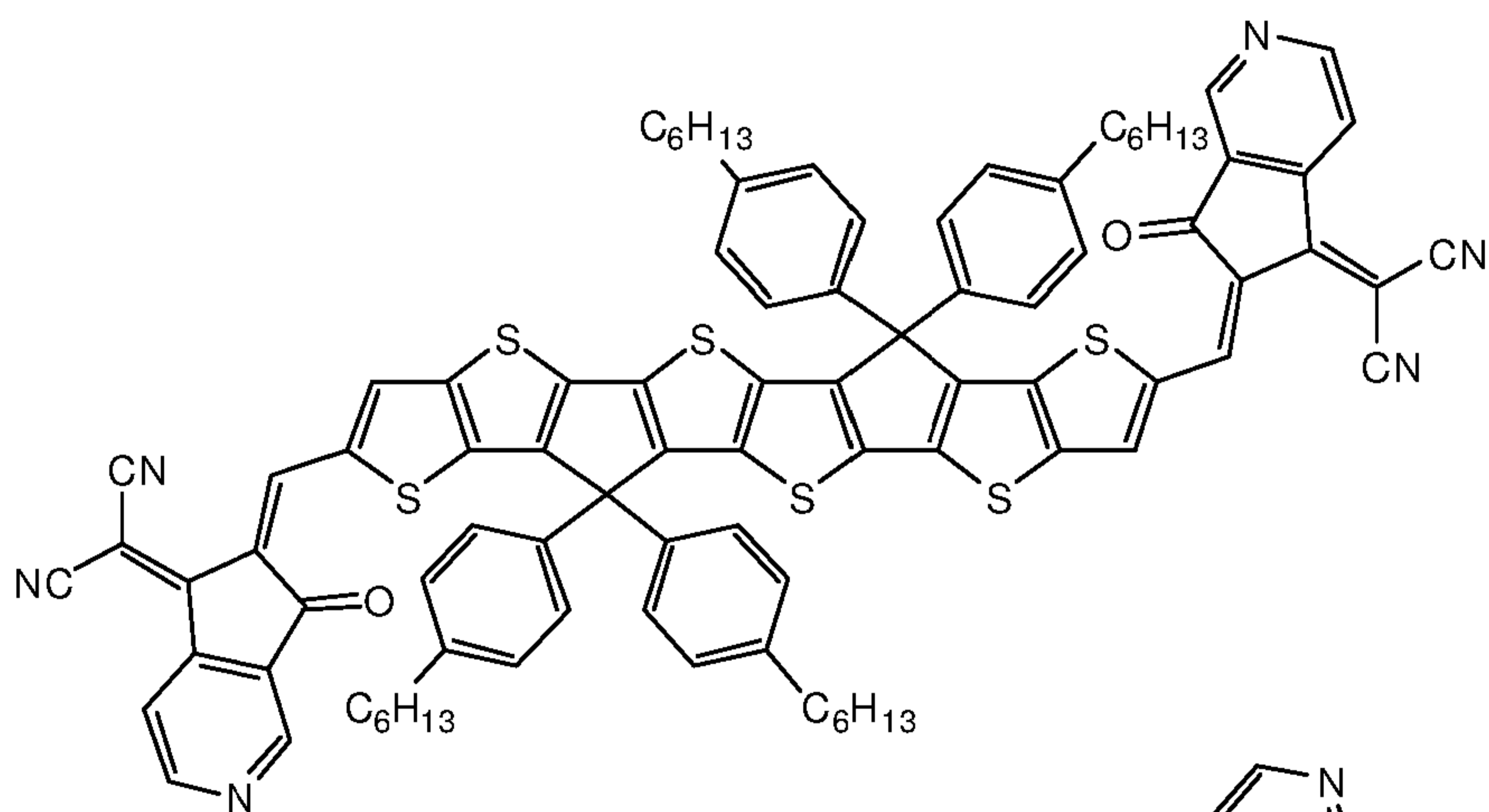
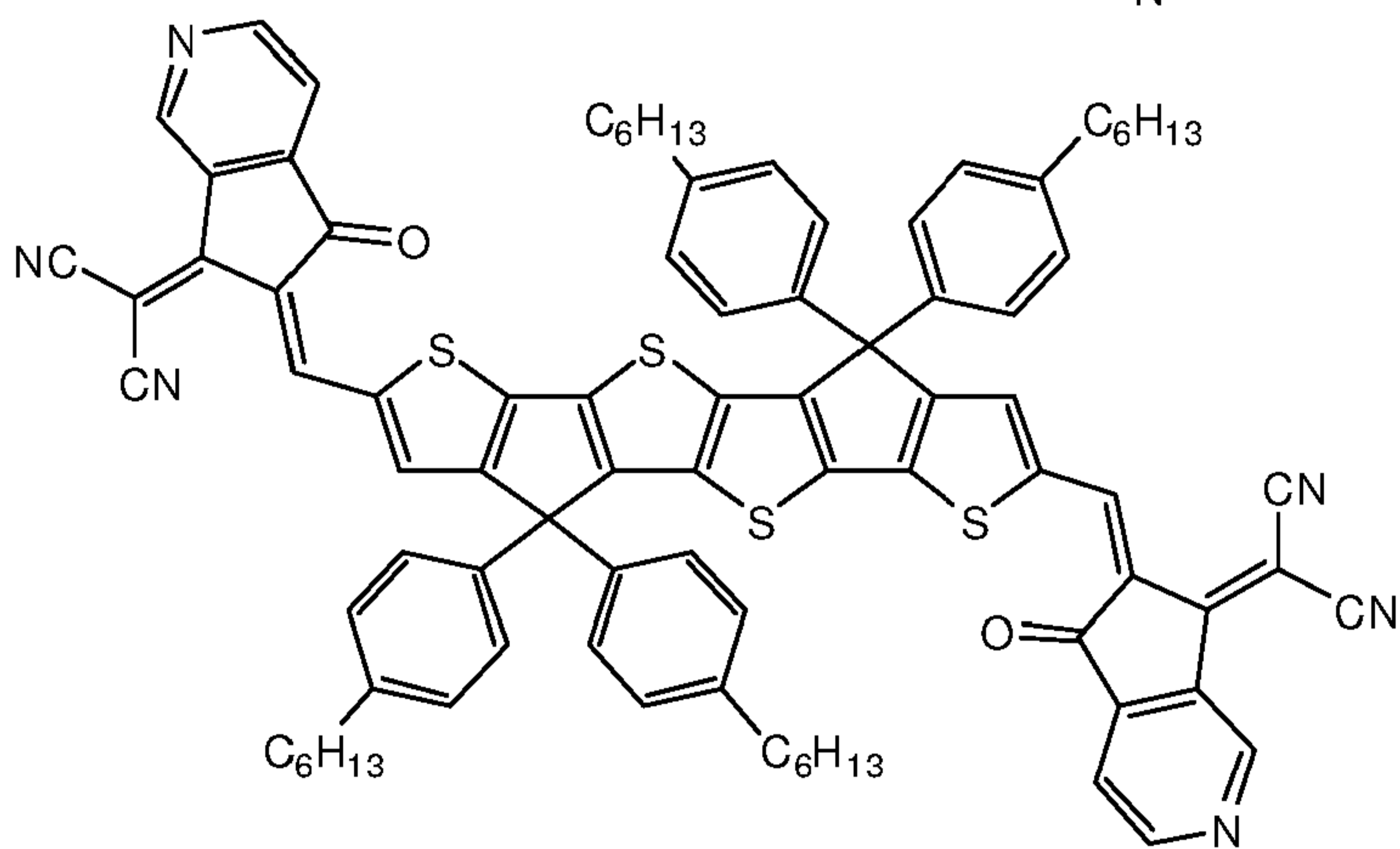
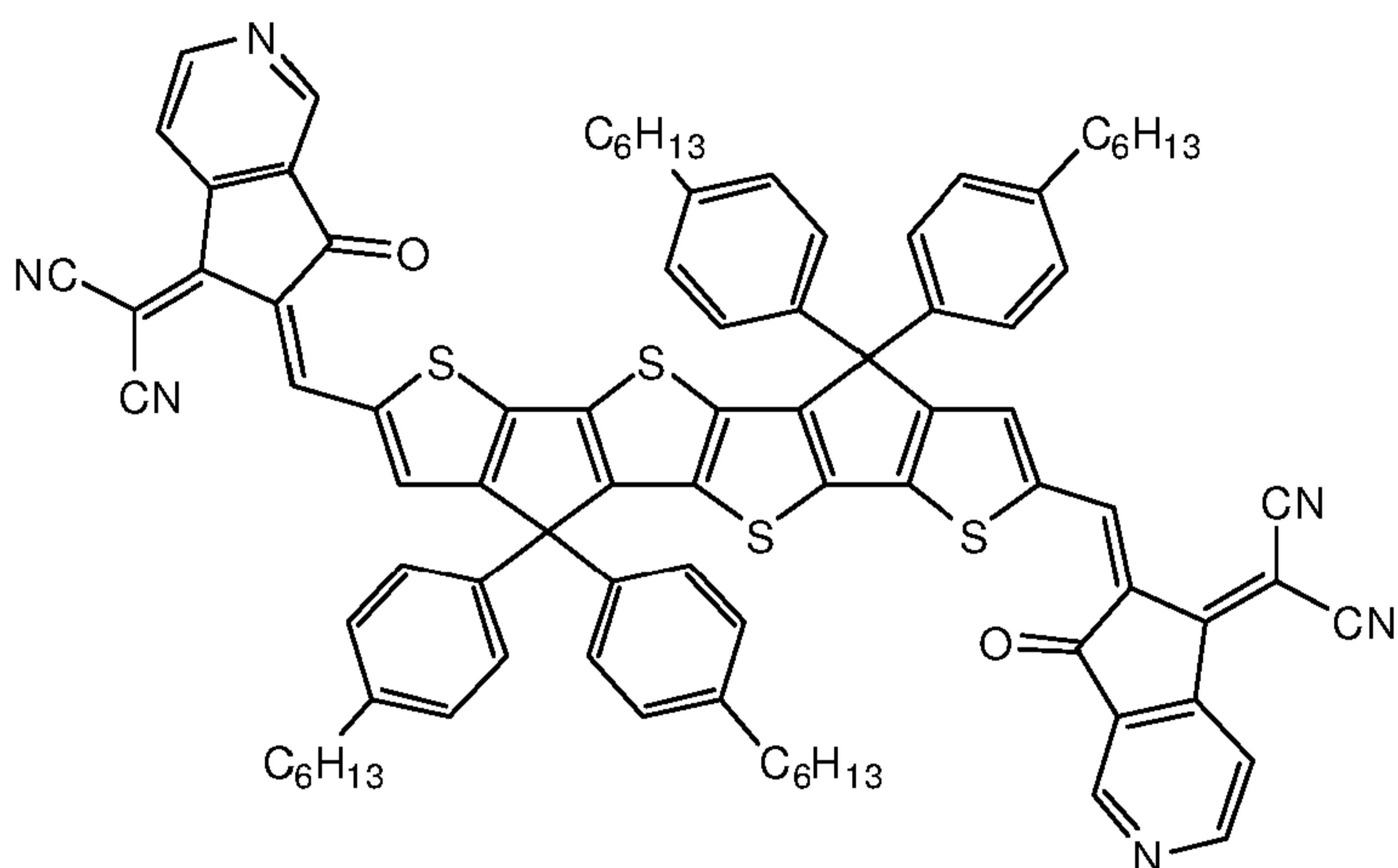
By “non-terminal” C atom of an alkyl group as used herein is meant a C atom of the alkyl other than the methyl C atom of a linear (n-alkyl) chain or the methyl C atoms of a branched alkyl chain.

Exemplary compounds of formula (I) are:









The donor (p-type) compound is not particularly limited and may be appropriately selected from electron donating materials that are known to the person skilled in the art, including organic polymers and non-polymeric organic molecules. The p-type compound has a HOMO deeper (further from vacuum) than a LUMO of the compound of formula (I). Optionally, the gap between the HOMO level of the p-type donor and the LUMO level of the n-type acceptor compound of formula (I) is less than 1.4 eV.

In a preferred embodiment the p-type donor compound is an organic conjugated polymer, which can be a homopolymer or copolymer including alternating, random or block copolymers. Preferred are non-crystalline or semi-crystalline conjugated organic polymers. Further preferably the p-type organic semiconductor is a conjugated organic polymer with a low bandgap, typically between 2.5 eV and 1.5 eV, preferably between 2.3 eV and 1.8 eV.

Optionally, the p-type donor has a HOMO level no more than 5.5 eV from vacuum level. Optionally, the p-type donor has a HOMO level at least 4.1 eV from vacuum level.

As exemplary p-type donor polymers, polymers selected from conjugated hydrocarbon or heterocyclic polymers including polyacene, polyaniline, polyazulene, polybenzofuran, polyfluorene, polyfuran, polyindenofluorene, polyindole, polyphenylene, polypyrazoline, polypyrene, polypyridazine, polypyridine, polytriarylamine, poly(phenylene vinylene), poly(3-substituted thiophene), poly(3,4-bisubstituted thiophene), polyselenophene, poly(3-substituted selenophene), poly(3,4-bisubstituted selenophene), poly(bisthiophene), poly(terthiophene), poly(bisselenophene), poly(terselenophene), polythieno[2,3-b]thiophene, polythieno[3,2-b]thiophene, polybenzothiophene, polybenzo[1,2-b:4,5-b']dithiophene, polyisothianaphthene, poly(monosubstituted pyrrole), poly(3,4-bisubstituted pyrrole), poly-1,3,4-oxadiazoles, polyisothianaphthene, derivatives and co-polymers thereof may be mentioned. Preferred examples of p-type donors are copolymers of polyfluorenes and polythiophenes, each of which may be substituted, and polymers comprising benzothiadiazole-based and thiophene-based repeating units, each of which may be substituted. It is understood that the p-type donor may also consist of a mixture of a plurality of electron donating materials.

In some embodiments, the weight of the donor compound to the acceptor compound is from about 1:0.5 to about 1:2.

Preferably, the weight ratio of the donor compound to the acceptor compound is about 1:1 or about 1:1.5.

5 At least one of the first and second electrodes is transparent so that light incident on the device may reach the bulk heterojunction layer. In some embodiments, both of the first and second electrodes are transparent.

Each transparent electrode preferably has a transmittance of at least 70 %, optionally at least 80 %, to wavelengths in the range of 300-900 nm.

10 In some embodiments, one electrode is transparent and the other electrode is reflective.

Optionally, the transparent electrode comprises or consists of a layer of transparent conducting oxide, preferably indium tin oxide or indium zinc oxide. In preferred embodiments, the electrode may comprise poly 3,4-ethylenedioxythiophene (PEDOT). In other preferred embodiments, the electrode may comprise a mixture of PEDOT and polystyrene sulfonate (PSS). The electrode may consist of a layer of PEDOT:PSS.

Optionally, the reflective electrode may comprise a layer of a reflective metal. The layer of reflective material may be aluminium or silver or gold. In some embodiments, a bi-layer electrode may be used. For example, the electrode may be an indium tin oxide (ITO)/silver bi-layer, an ITO/aluminium bi-layer or an ITO/gold bi-layer.

20 The device may be formed by forming the bulk heterojunction layer over one of the anode and cathode supported by a substrate and depositing the other of the anode or cathode over the bulk heterojunction layer.

The area of the OPD may be less than about 3 cm², less than about 2 cm², less than about 1 cm², less than about 0.75 cm², less than about 0.5 cm² or less than about 0.25 cm². The substrate may be, without limitation, a glass or plastic substrate. The substrate can be described as an inorganic semiconductor. In some embodiments, the substrate may be silicon. For example, the substrate can be a wafer of silicon. The

substrate is transparent if, in use, incident light is to be transmitted through the substrate and the electrode supported by the substrate.

The substrate supporting one of the anode and cathode may or may not be transparent if, in use, incident light is to be transmitted through the other of the anode and cathode.

5 The bulk heterojunction layer may be formed by any process including, without limitation, thermal evaporation and solution deposition methods.

Preferably, the bulk heterojunction layer is formed by depositing a formulation comprising the acceptor material and the electron donor material dissolved or dispersed in a solvent or a mixture of two or more solvents. The formulation may be deposited by
10 any coating or printing method including, without limitation, spin-coating, dip-coating, roll-coating, spray coating, doctor blade coating, wire bar coating, slit coating, ink jet printing, screen printing, gravure printing and flexographic printing.

The one or more solvents of the formulation may optionally comprise or consist of benzene substituted with one or more substituents selected from chlorine, C₁₋₁₀ alkyl and
15 C₁₋₁₀ alkoxy wherein two or more substituents may be linked to form a ring which may be unsubstituted or substituted with one or more C₁₋₆ alkyl groups, optionally toluene, xylenes, trimethylbenzenes, tetramethylbenzenes, anisole, indane and its alkyl-substituted derivatives, and tetralin and its alkyl-substituted derivatives.

The formulation may comprise a mixture of two or more solvents, preferably a mixture
20 comprising at least one benzene substituted with one or more substituents as described above and one or more further solvents. The one or more further solvents may be selected from esters, optionally alkyl or aryl esters of alkyl or aryl carboxylic acids, optionally a C₁₋₁₀ alkyl benzoate, benzyl benzoate or dimethoxybenzene. In preferred embodiments, a mixture of trimethylbenzene and benzyl benzoate is used as the solvent.
25 In other preferred embodiments, a mixture of trimethylbenzene and dimethoxybenzene is used as the solvent.

The formulation may comprise further components in addition to the electron acceptor, the electron donor and the one or more solvents. As examples of such components, adhesive agents, defoaming agents, deaerators, viscosity enhancers, diluents, auxiliaries,

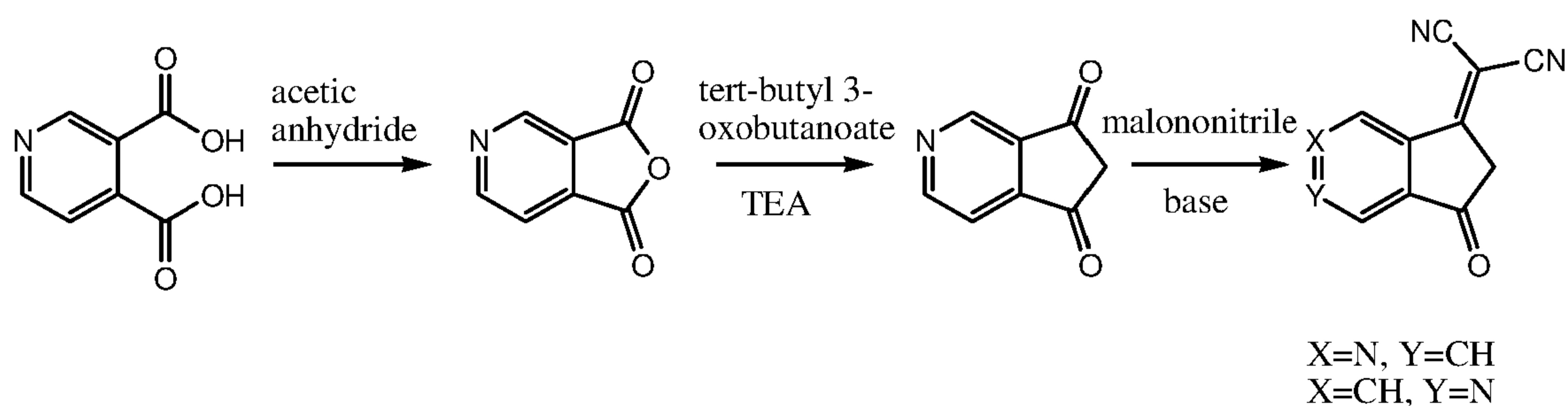
flow improvers colourants, dyes or pigments, sensitizers, stabilizers, nanoparticles, surface-active compounds, lubricating agents, wetting agents, dispersing agents and inhibitors may be mentioned.

The organic photodetector as described herein may be used in a wide range of applications including, without limitation, detecting the presence and / or brightness of ambient light and in a sensor comprising the organic photodetector and a light source. The photodetector may be configured such that light emitted from the light source is incident on the photodetector and changes in wavelength and / or brightness of the light may be detected, e.g. due to absorption by and / or emission of light from a target material in a sample disposed in a light path between the light source and the organic photodetector. The sensor may be, without limitation, a gas sensor, a biosensor, an X-ray imaging device, an image sensor such as a camera image sensor, a motion sensor (for example for use in security applications) a proximity sensor or a fingerprint sensor. A 1D or 2D photosensor array may comprise a plurality of photodetectors as described herein in an image sensor.

Examples

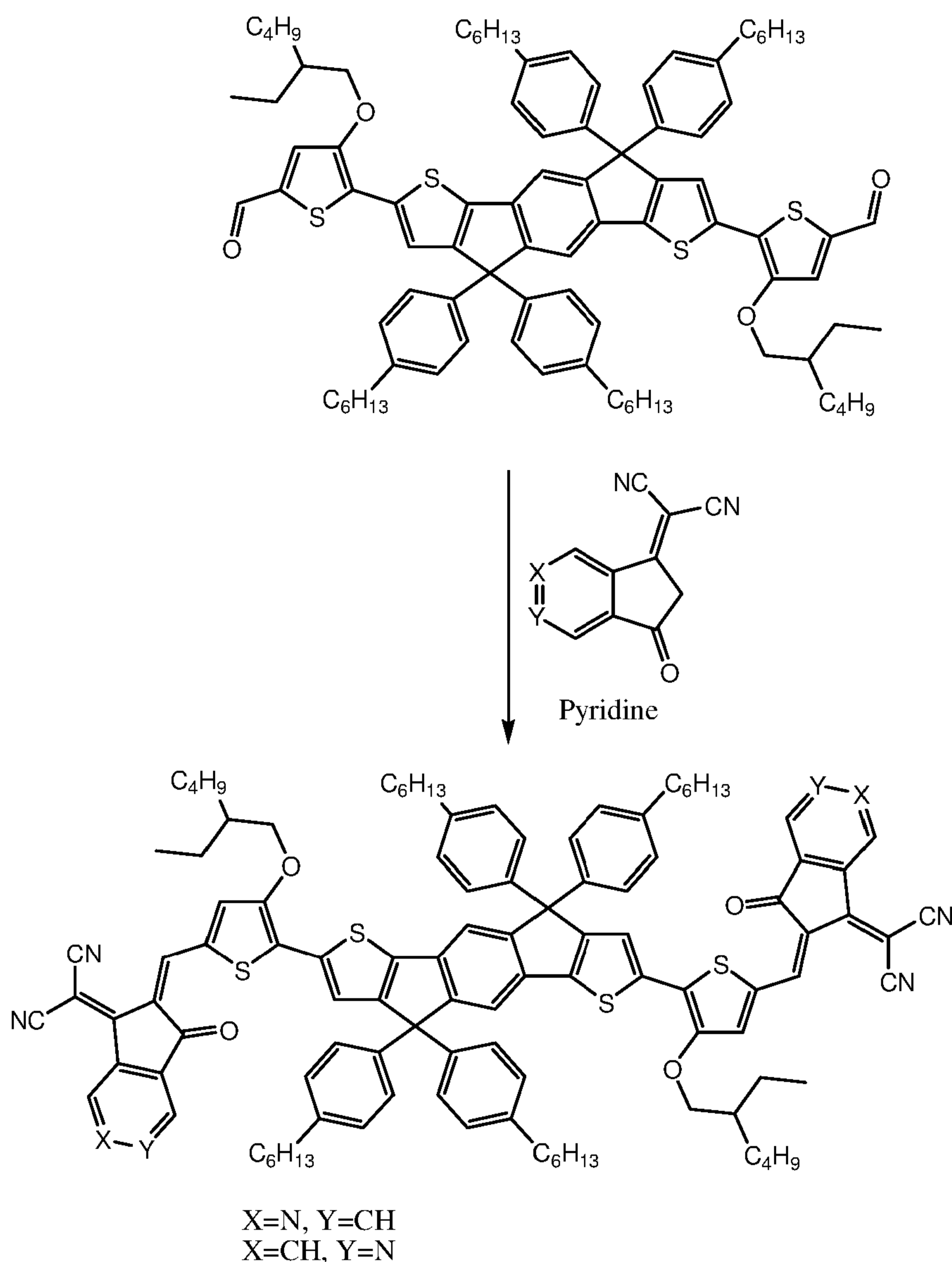
Synthesis

An electron-acceptor group precursor (mixture of isomers) was prepared according to the following reaction scheme:



20

Compound Example 1 was formed by reaction of the electron-acceptor group precursor according to the following reaction scheme:



Step 1 & 2

Pyridine-3,4-dicarboxylic acid (10 g, 59.8 mmol) was refluxed in acetic anhydride (70 mL) under nitrogen atmosphere for 30 mins. After cooling, trimethylamine (16.5 mL, 119 mmol) was added dropwise followed by tert-butyl 3-oxobutanoate (9.46 g, 59.8 mmol) and the reaction mixture was stirred at room temperature for 18 h. The volatiles were removed leave a crude material. The crude material was purified by column chromatography on silica eluting with 10% methanol in DCM to yield 12 g of a gummy solid. The material was dissolved in water and cooled in an ice bath. 1.5 N HCl (100 mL) and conc HCl (5 mL) was added to acidify the mixture to pH 2-3. A brown precipitate was formed and isolated by filtration. The solid was triturated with acetone

twice and then filtered and dried. 5 g of this material was recrystallized from acetonitrile and placed in the freezer overnight yielding 2.9 g of crude bis-ketone.

Step 3

5 Malononitrile (7.79 g, 118 mmol) was dissolved in ethanol (300 mL) under nitrogen atmosphere. Sodium acetate (8.07 g, 98.4 mmol) was added and the mixture was stirred for 1 h at room temperature. The crude stage 2 material (2.9 g) was added portion-wise to the mixture and stirred for 16 h. The reaction mixture was concentrated and the crude was taken in acetone (300 mL) and stirred for 4 h. The solid was removed by filtration and the filtrate was concentrated to obtain 12 g of crude. The crude was purified by
10 reverse phase column chromatography eluting with 10% acetonitrile in water. The product-containing fractions were concentrated and placed in the freezer to obtain 600 mg. The product was suspended in 1.5N HCl (25 mL) and placed in a freeze dryer. Upon completion it was used in the next step without further purification.

Step 4

15 The thiophene core (400 mg, 288 μ mol) and stage 3 material (562 mg, 115 μ mol) were dissolved in chloroform under nitrogen atmosphere. Pyridine (5 mL) was added and the reaction was stirred at 65 °C for 65 h. After cooling the solvents were removed and the crude residue was purified by column chromatography on silica eluting with 2% methanol in chloroform. The product-containing fractions were concentrated and
20 triturated with acetonitrile for 3 h. After filtration the solid was precipitated from DCM/hexanes (3/30 mL) twice and the solid was filtered and dried to give 495 mg of product. LCMS showed a purity of 98.31%.

Modelling data

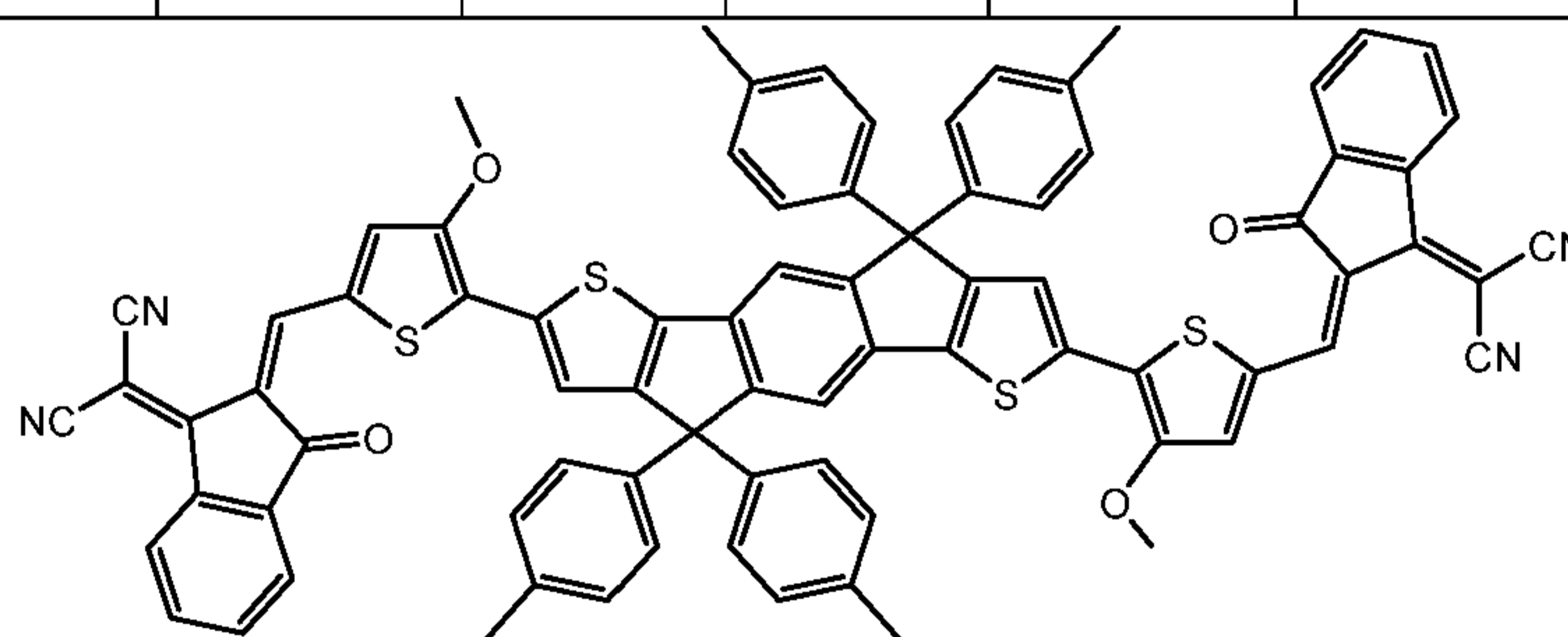
25 LUMO levels and HOMO-LUMO bandgaps of compounds of formula (Ib) were modelled in which R¹, R², R⁵ and R⁸ are each methyl; R³, R⁴, R⁶, R⁷, R⁹ and R¹⁰ are each H; and X¹-X⁴ are as in Table 1.

For comparison, compounds in which X¹-X⁴ groups of formula (Ib) are either C-H or C-F replaced with F were also modelled.

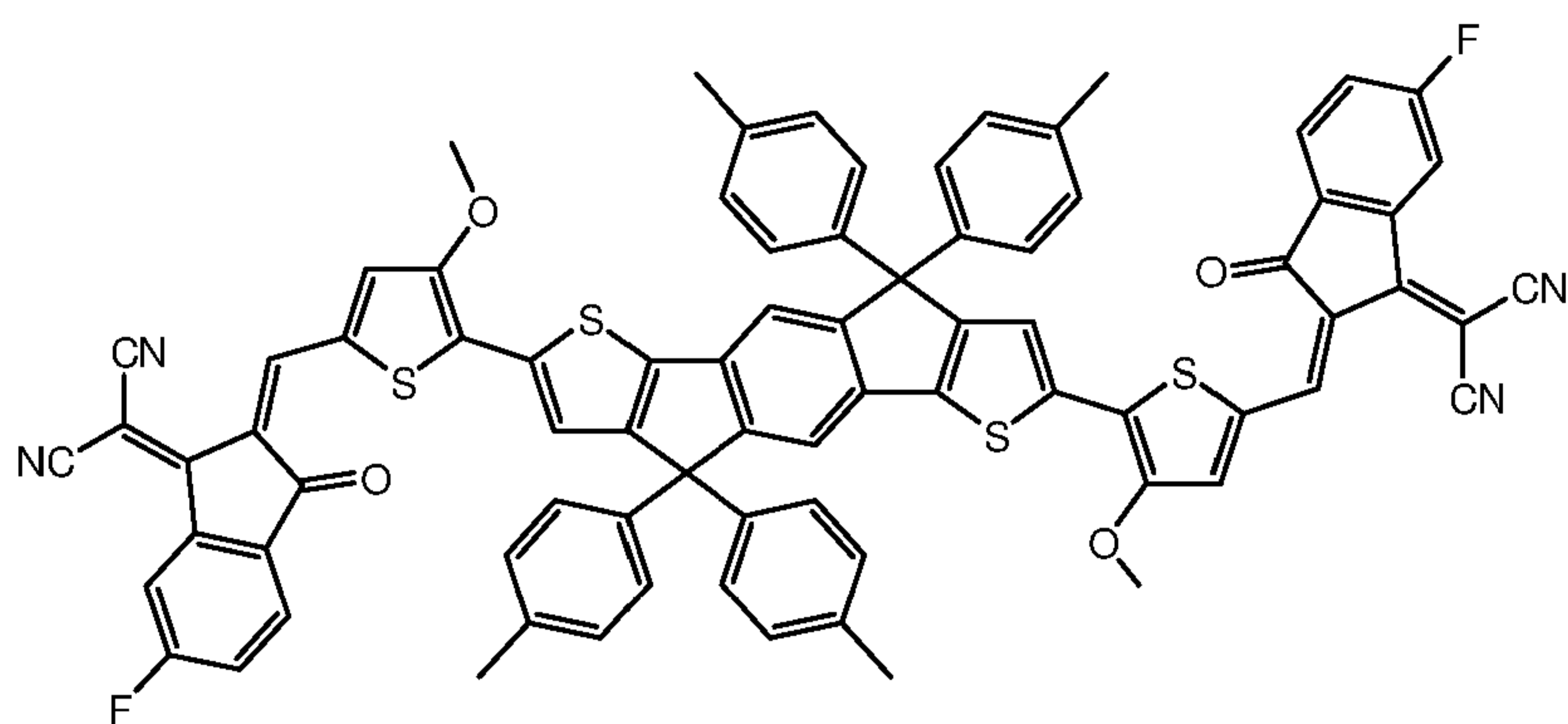
Quantum chemical modelling was performed using Gaussian09 software available from Gaussian using Gaussian09 with B3LYP (functional) and LACVP* (Basis set).

Table 1

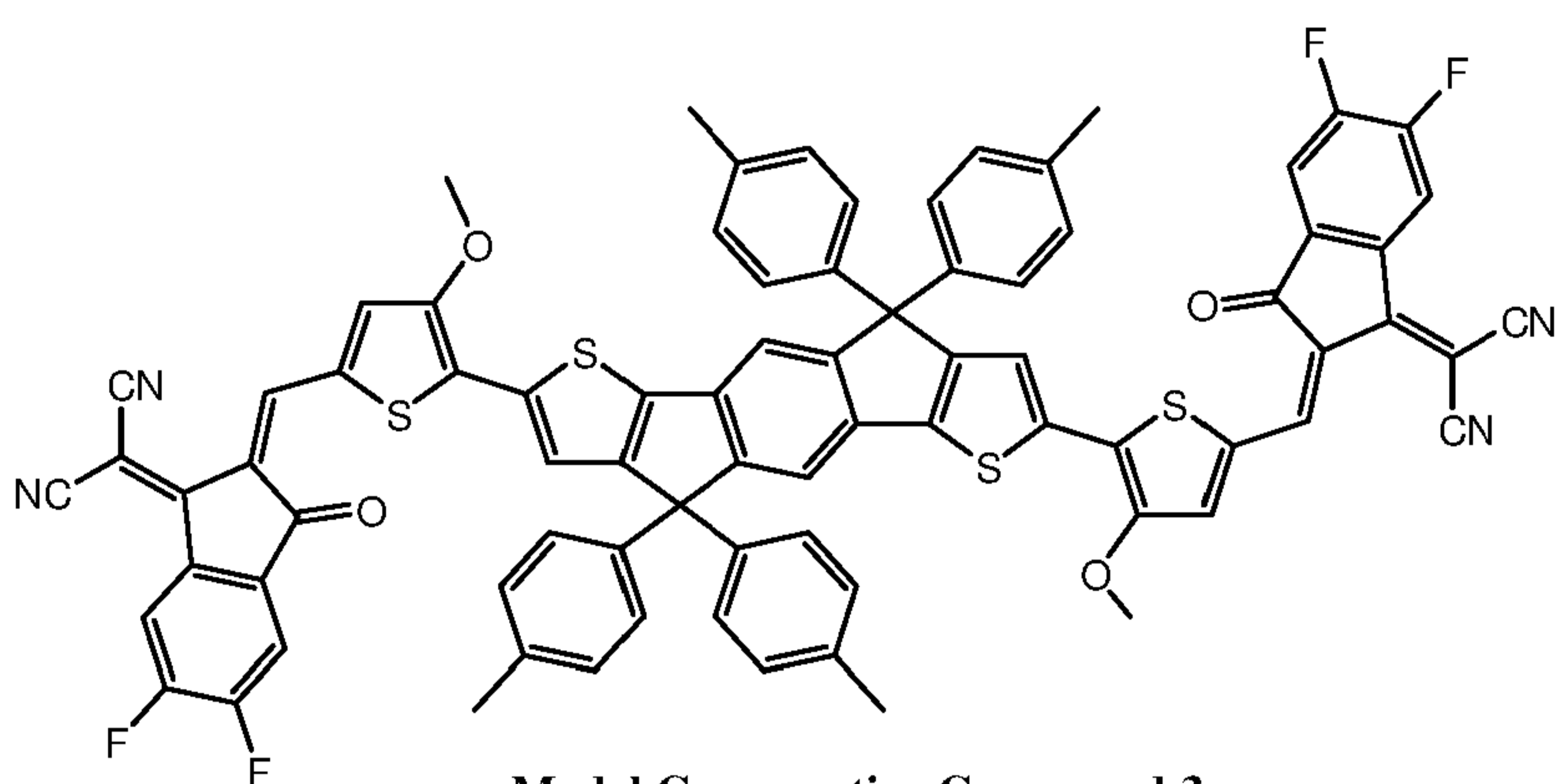
Compound	X ¹	X ²	X ³	X ⁴	LUMO (eV)	Band gap (eV)
Model Comparative Compound 1	CH	CH	CH	CH	3.26	1.77
Model Comparative Compound 2	CH	CF	CH	CH	3.36	1.73
Model Comparative Compound 3	CH	CF	CF	CH	3.39	1.74
Model Compound Example 1	CH	CH	N	CH	3.50	1.69
Model Compound Example 2	CH	N	CH	CH	3.46	1.75



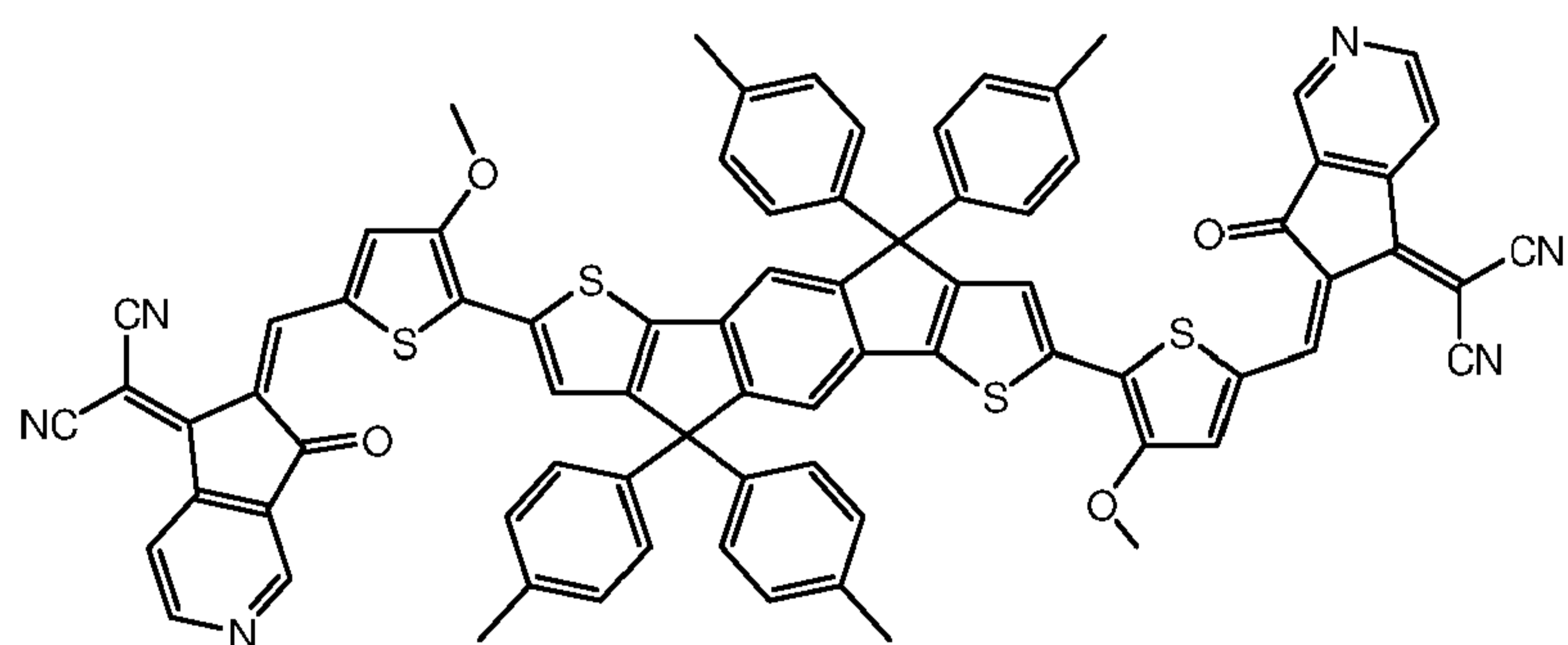
Model Comparative Compound 1



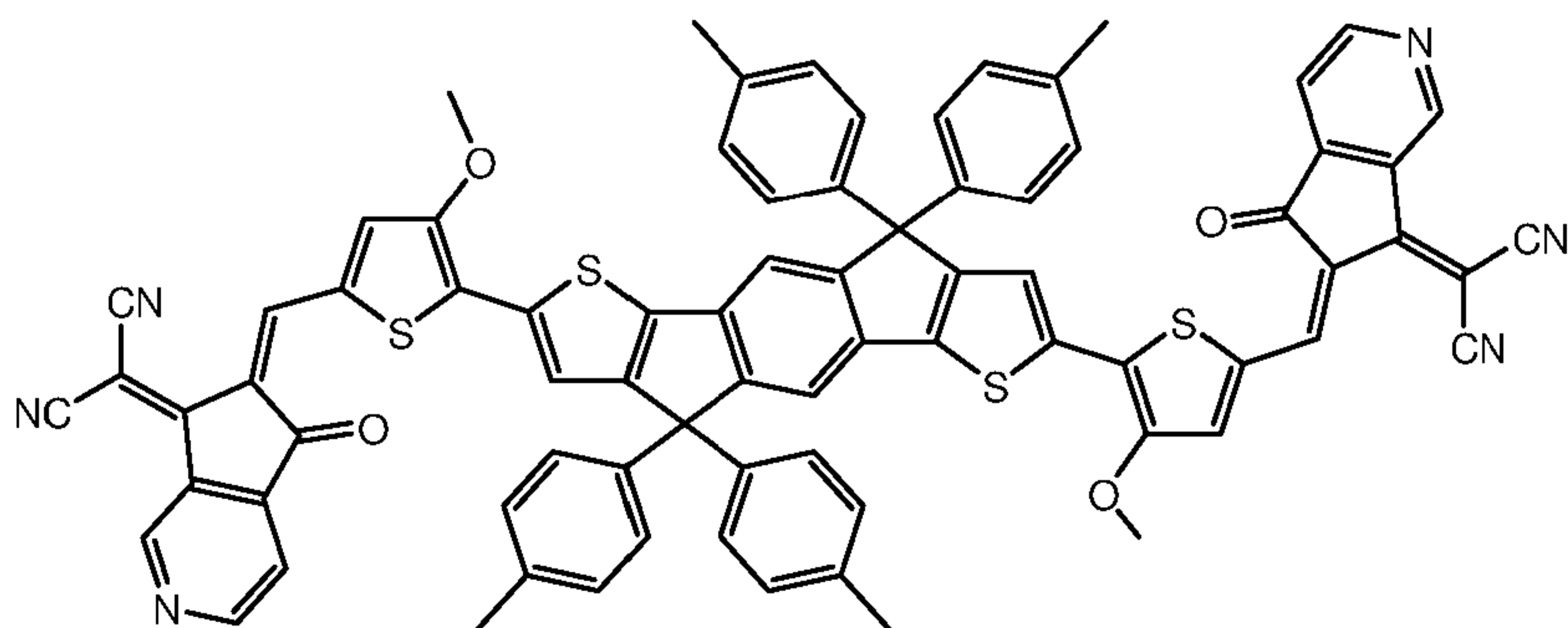
Model Comparative Compound 2



Model Comparative Compound 3



Model Compound Example 1

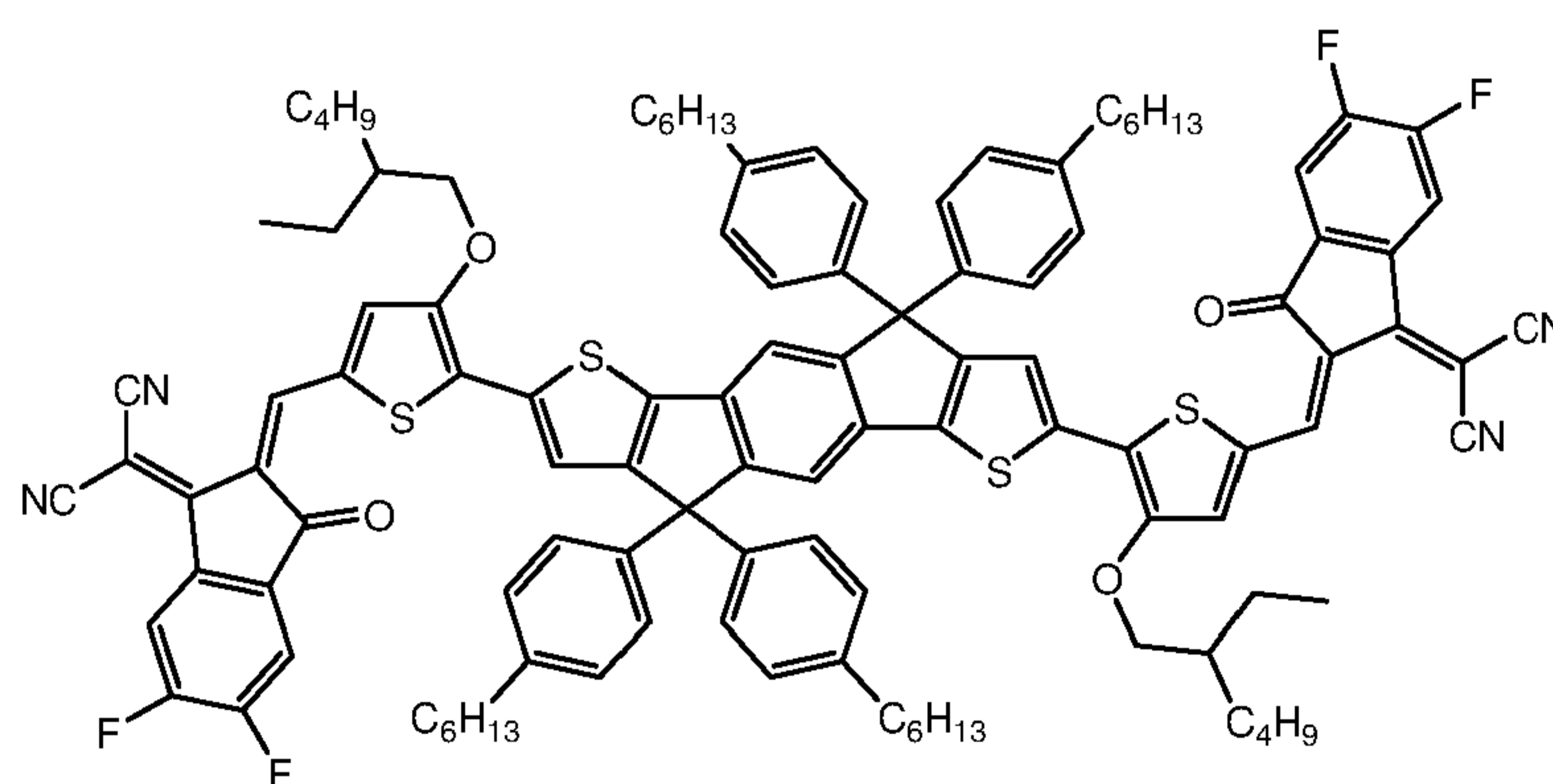


Model Compound Example 2

With reference to Table 1, Model Compound Examples 1 and 2 have a LUMO which is deeper (i.e. further from vacuum level) and a similar or smaller band gap than Model Comparative Compounds 1-3.

Absorption

- 5 Figure 2 shows absorption spectra for Compound Example 1 and comparative compound IEICO-4F. Compound Example 1 has a significantly longer peak wavelength (786 nm) than IEICO-4F (762 nm).



IEICO-4F

10 HOMO and LUMO Energy Levels

HOMO and LUMO levels of films of Compound Example 1 and comparative compound IEICO-4F were determined by square wave voltammetry (SWV) and the results are set out in Table 2.

- 15 The LUMO level of Compound Example 1 is deeper and its HOMO-LUMO gap is smaller as compared to comparative compound IEICO-4F having a structure of Compound Example 1 except that each X² and X³ is CF.

Table 2

	Film HOMO /eV	Film LUMO /eV	HOMO-LUMO gap (eV)

CompoundExample 1	-5.45	-4.07	1.38
IEICO-4F (comparative)	-5.45	-4.03	1.42

The HOMO and LUMO energy levels of compounds reported herein were determined from films of the compounds using SWV at room temperature. In SWV, the current at a working electrode is measured while the potential between the working electrode and a reference electrode is swept linearly in time. The difference current between a forward and reverse pulse is plotted as a function of potential to yield a voltammogram. The apparatus to measure HOMO or LUMO energy levels by SWV may comprise a cell containing tertiary butyl ammonium perchlorate or tertiary butyl ammonium hexafluorophosphate in acetonitrile; a glassy carbon working electrode; a platinum counter electrode and a leak free Ag/AgCl reference electrode.

Ferrocene is added directly to the existing cell at the end of the experiment for calculation purposes where the potentials are determined for the oxidation and reduction of ferrocene versus Ag/AgCl using cyclic voltammetry (CV).

Apparatus:

CHI 660D Potentiostat.

3mm Diameter glassy carbon working electrode

Leak free Ag/AgCl reference electrode

Pt wire auxiliary or counter electrode.

0.1 M Tetrabutylammonium hexafluorophosphate in acetonitrile.

Method:

The sample is dissolved in toluene (3mg/ml) and spun at 3000 rpm directly on to the glassy carbon working electrode.

LUMO = 4.8-E ferrocene (peak to peak average) - E reduction of sample (peak maximum).

5 HOMO = 4.8-E ferrocene (peak to peak average) + E oxidation of sample (peak maximum).

A typical SWV experiment runs at 15 Hz frequency; 25 mV amplitude and 0.004 V increment steps. Results are calculated from 3 freshly spun film samples for both the HOMO and LUMO data.

10 All experiments are run under an Argon gas purge.

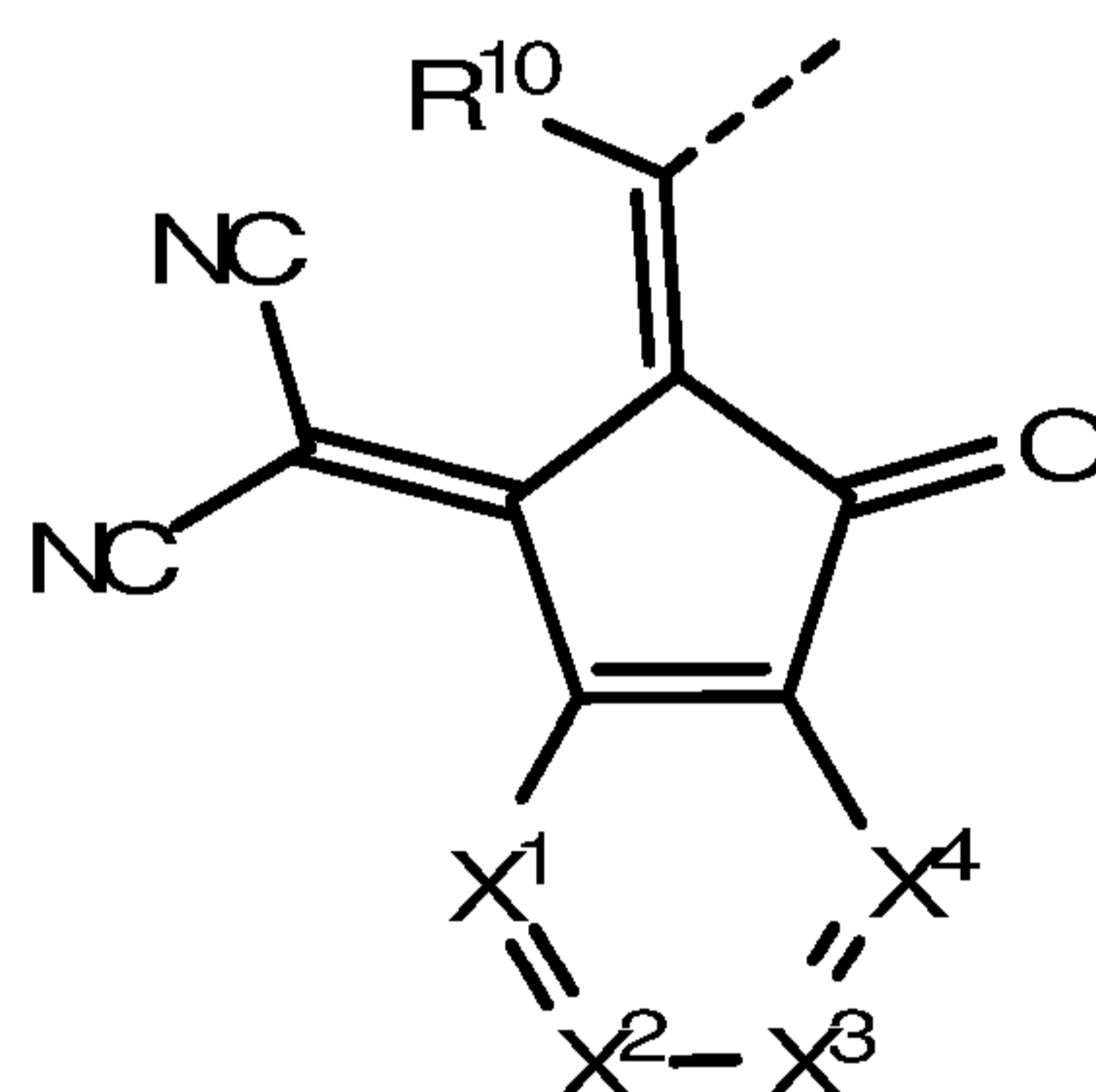
Claims

- 1) A compound of formula (I):



(I)

- 5 wherein EDG is an electron-donating group comprising a polycyclic heteroaromatic group and each EAG is an electron-accepting group of formula (II):



(II)

- 10 wherein R¹⁰ in each occurrence is H or a substituent;

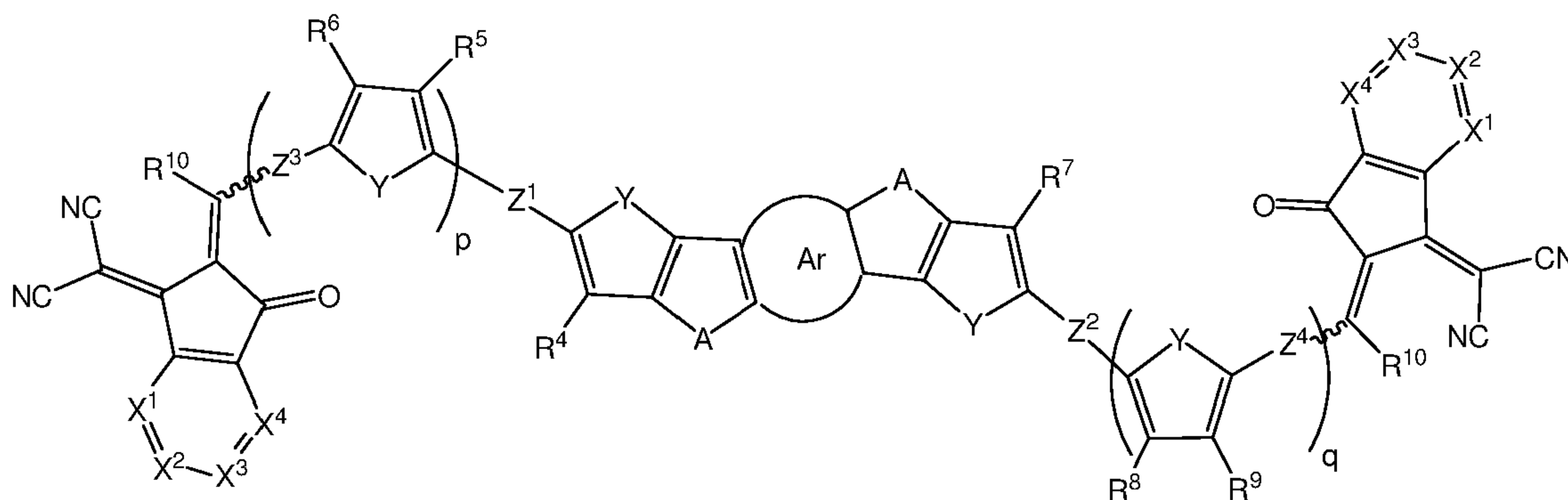
---- is a bond to EDG; and

each X¹-X⁴ is independently CR¹¹ or N wherein R¹¹ in each occurrence is H or a substituent, with the proviso that at least one occurrence of at least one of X¹-X⁴ is N.

15

- 2) The compound according to claim 1 wherein each X³ is N.
- 3) The compound according to claim 2 wherein each X¹, X² and X⁴ is CR¹¹.
- 4) The compound according to any one of the preceding claims wherein each R¹¹ is independently selected from H and C₁₋₁₂ alkyl.

- 5) The compound according to any one of the preceding claims wherein the compound has formula (Ia):



5

(Ia)

wherein:

Ar is furan, thiophene or benzene which is unsubstituted or substituted with one or more substituents;

each Y is independently O or S;

10 each A is independently O, S or CR¹R² wherein R¹ and R² independently in each occurrence is a substituent;

each R⁴-R⁹ is independently H or a substituent;

p is 0, 1, 2 or 3;

q is 0, 1, 2 or 3;

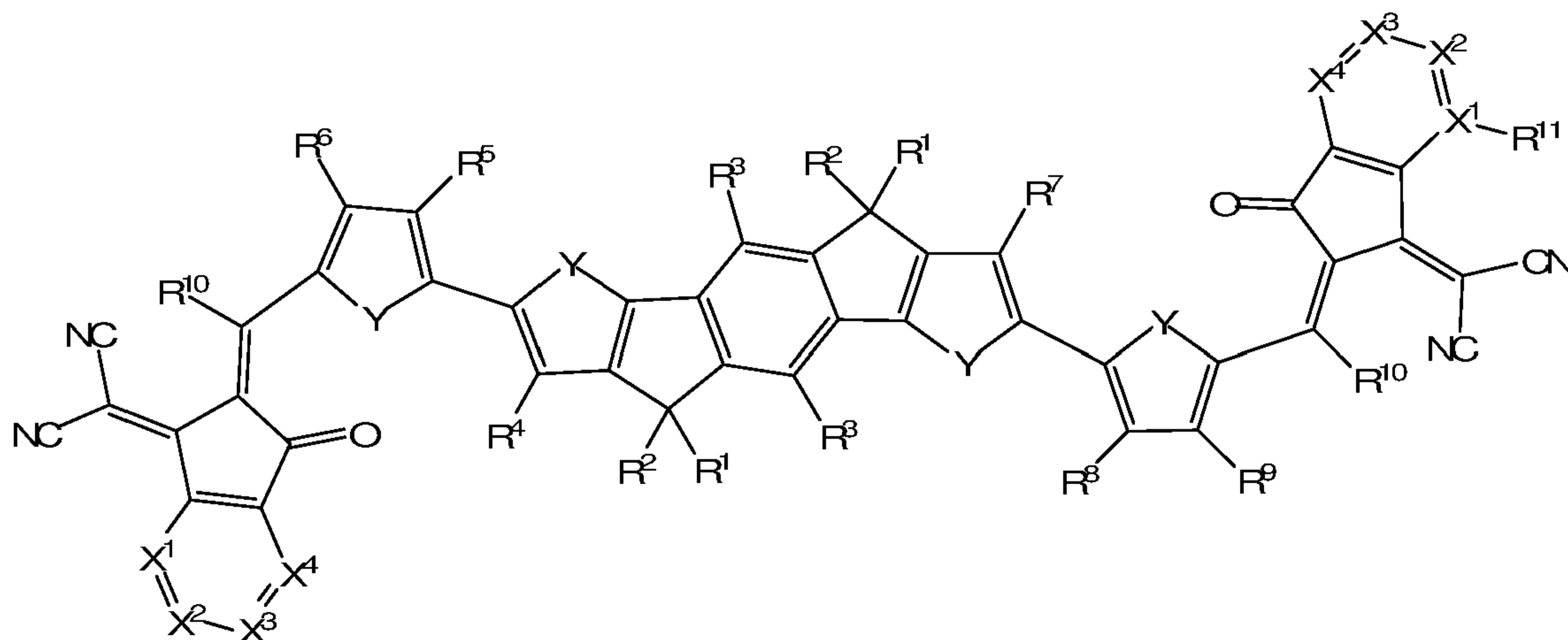
15 Z¹ is a direct bond or, together with R⁴ or R⁵, forms an aromatic or heteroaromatic group Ar¹;

Z² is a direct bond or, together with R⁷ or R⁸, forms an aromatic or heteroaromatic group Ar²;

20 Z³ is a direct bond or, together with R⁶, forms an aromatic or heteroaromatic group Ar³; and

Z^4 is a direct bond or, together with R^9 , forms an aromatic or heteroaromatic group Ar^4 .

- 6) The compound according to claim 5 wherein the compound has formula (Ib):



5

(Ib)

wherein each R³ is, independently in each occurrence, H or a substituent.

- 7) The compound according to claim 5 or 6 wherein R¹ and R² independently in each occurrence are selected from the group consisting of:

10 linear, branched or cyclic C₁₋₂₀ alkyl wherein one or more non-adjacent, non-terminal C atoms may be replaced by O, S, NR¹², CO or COO wherein R¹² is a C₁₋₁₂ hydrocarbyl and one or more H atoms of the C₁₋₂₀ alkyl may be replaced with F; and

15 a group of formula (Ak)_u-(Ar⁶)_v wherein Ak is a C₁₋₁₂ alkylene chain in which one or more C atoms may be replaced with O, S, CO or COO; u is 0 or 1; Ar⁶ in each occurrence is independently an aromatic or heteroaromatic group which is unsubstituted or substituted with one or more substituents; and v is at least 1.

- 8) The compound according to claim 7 wherein at least one of R¹ and R² is phenyl which is unsubstituted or substituted with one or more substituents selected from C₁₋₂₀ alkyl wherein one or more non-adjacent, non-terminal C atoms may be
- 20

replaced by O, S, NR¹², CO or COO and one or more H atoms of the C₁₋₂₀ alkyl may be replaced with F.

- 9) The compound according to any one of claims 5-8 wherein each R⁴-R⁹ is independently selected from:

5 H;

C₁₋₁₂ alkyl wherein one or more non-adjacent, non-terminal C atoms may be replaced with O, S, COO or CO; and

an aromatic or heteroaromatic group Ar⁵ which is unsubstituted or substituted with one or more substituents.

- 10 10) The compound according to any one of claims 6-9 wherein each R³ independently in each occurrence is selected from:

H;

C₁₋₁₂ alkyl wherein one or more non-adjacent, non-terminal C atoms may be replaced with O, S, COO or CO; and

15 an aromatic or heteroaromatic group Ar⁵ which is unsubstituted or substituted with one or more substituents.

- 11) A composition comprising a compound of formula (I) according to any one of the preceding claims and an electron-donating material capable of donating an
20 electron to the compound.

- 12) A formulation comprising a compound or composition according to any one of the preceding claims dissolved or dispersed in one or more solvents.

- 13) An organic photodetector comprising: an anode; a cathode; and a photosensitive organic layer disposed between the anode and cathode wherein the

photosensitive organic layer comprises a donor compound and an acceptor compound according to any one of the preceding claims.

- 14) A method of forming an organic photodetector according to claim 13 comprising formation of the photosensitive organic layer over one of the anode and cathode and formation of the other of the anode and cathode over the photosensitive organic layer.
- 15) A method according to claim 16 wherein formation of the photosensitive organic layer comprises deposition of the formulation according to claim 11 and evaporation of the one or more solvents.
- 16) A photosensor comprising a light source and an organic photodetector according to claim 11 configured to detect light emitted from the light source.
- 17) A photosensor according to claim 12 wherein the light source emits light having a peak wavelength greater than 750 nm.
- 18) A photosensor according to claim 16 or 17 configured to receive a sample in a light path between the organic photodetector and the light source.
- 19) A method of determining the presence and / or concentration of a target material in a sample, the method comprising illuminating the sample and measuring a response of a photodetector according to claim 14 or 15 configured to receive light emitted from the sample upon illumination.
- 20) A method according to claim 19 wherein the organic photodetector is the organic photodetector of a photosensor according to any one of claims 16-18.



Application No: GB1819623.8

Examiner: Mr Robert Goodwill

Claims searched: 1-20

Date of search: 17 May 2019

Patents Act 1977: Search Report under Section 17

Documents considered to be relevant:

Category	Relevant to claims	Identity of document and passage or figure of particular relevance
X	1, 4-20	US 5112759 A (SENOO), see compounds 104, 106, 110 and claims
X	1, 4-20	JP H0312658 A (CANON), see compounds (4), (6) and (10)

Categories:

X	Document indicating lack of novelty or inventive step	A	Document indicating technological background and/or state of the art.
Y	Document indicating lack of inventive step if combined with one or more other documents of same category.	P	Document published on or after the declared priority date but before the filing date of this invention.
&	Member of the same patent family	E	Patent document published on or after, but with priority date earlier than, the filing date of this application.

Field of Search:

Search of GB, EP, WO & US patent documents classified in the following areas of the UKC^X :

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Worldwide search of patent documents classified in the following areas of the IPC

C07D; H01L

The following online and other databases have been used in the preparation of this search report

EPODOC, WPI, CAS Online, MARPAT

International Classification:

Subclass	Subgroup	Valid From
C07D	0495/22	01/01/2006
C07D	0495/04	01/01/2006
H01L	0051/42	01/01/2006